## PCTEST ENGINEERING LABORATORY, INC.



6660-B Dobbin Road, Columbia, MD 21045 USA Tel. 410.290.6652 / Fax 410.290.6654 http://www.pctestlab.com



## **HEARING AID COMPATIBILITY**

**Applicant Name:** 

Samsung Electronics Co., Ltd. 416 Maetan 3-Dong, Yeongtong-gu, Suwon-si Gyeonggi-do, 443-742, Republic of Korea

0Y1210

Date of Testing:
October 18-24, 2012
Test Site/Location:
PCTEST Lab, Columbia, MD, USA
Test Report Serial No.:
311563.A3L

FCC ID: A3LGTI9023

APPLICANT: SAMSUNG ELECTRONICS CO., LTD.

Application Type: Certification

**FCC Rule Part(s):** § 20.19(b), §6.3(v), §7.3(v)

**HAC Standard:** ANSI C63.19-2007; **EUT Type:** Portable Handset

Model(s): GT-I9023

**Tx Frequencies Tested:** 824.20 - 848.80 MHz (GSM 850)

1850.20 - 1909.80 MHz (GSM 1900) 1712.4 - 1752.5 MHz (AWS WCDMA)

**Test Device Serial No.:** Production Sample [S/N: 144]

C63.19-2007 HAC Category: M3 (RF EMISSIONS CATEGORY)

This wireless portable device has been shown to be hearing-aid compatible under the above rated category, specified in ANSI/IEEE Std. C63.19-2007 and had been tested in a ccordance with the specified measurement procedures. Hearing-Aid Compatibility is based on the assumption that all production units will be designed electrically identical to the device tested in this report. Test results reported herein relate only to the item(s) tested.

I attest to the accuracy of data. All measurements reported herein were performed by me or were made under my supervision and are correct to the best of my knowledge and belief. I assume full responsibility for the completeness of these measurements and vouch for the qualifications of all persons taking them.

PCTEST certifies that no party to this application has been subject to a denial of Federal benefits that includes FCC benefits pursuant to Section 5301 of the Anti-Drug Abuse Act of 1988, 21 U.S.C. 862.

Randy Ortanez President





FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 1 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		rage 1 01 00

## TABLE OF CONTENTS

1.	INTRODUCTION	3
2.	TEST SITE LOCATION	4
3.	EUT DESCRIPTION	5
4.	ANSI/IEEE C63.19 PERFORMANCE CATEGORIES	6
5.	SYSTEM SPECIFICATIONS	7
6.	TEST PROCEDURE	13
7.	SYSTEM CHECK	15
8.	MODULATION FACTOR	18
9.	FCC 3G MEASUREMENT PROCEDURES	20
10.	OVERALL MEASUREMENT SUMMARY	21
11.	EQUIPMENT LIST	24
12.	MEASUREMENT UNCERTAINTY	25
13.	TEST DATA	26
14.	CALIBRATION CERTIFICATES	39
15.	CONCLUSION	75
16.	REFERENCES	76
17.	TEST PHOTOGRAPHS	78

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 2 of 80
0Y1210311563.A3L	October 18-24, 2012	2 Portable Handset		F aye 2 01 00

## 1. INTRODUCTION

On July 10, 2003, the Federal Communications Commission (FCC) adopted new rules requiring wireless manufacturers and service providers to provide digital wireless phones that are compatible with hearing aids. The FCC has modified the exemption for wireless phones under the Hearing Aid Compatibility Act of 1998 (HAC Act) in WT Docket 01-309 RM-8658<sup>1</sup> to extend the benefits of wireless telecommunications to individuals with hearing disabilities. These benefits encompass business, social and emergency communications, which increase the value of the wireless network for everyone. An estimated more than 10% of the population in the United States show signs of hearing impairment and of that fraction, almost 80% use hearing aids. Approximately 500 million people worldwide suffer from hearing loss.

## **Compatibility Tests Involved:**

The standard calls for wireless communications devices to be measured for:

- RF Electric-field emissions
- RF Magnetic-field emissions
- T-coil mode, magnetic-signal strength in the audio band
- T-coil mode, magnetic-signal frequency response through the audio band
- T-coil mode, magnetic-signal and noise articulation index

The hearing aid must be measured for:

- RF immunity in microphone mode
- RF immunity in T-coil mode

In the following tests and results, this report includes the evaluation for a wireless communications device.



Figure 1-1 Hearing Aid in-vitu

<sup>&</sup>lt;sup>1</sup> FCC Rule & Order, WT Docket 01-309 RM-8658

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 3 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		rage 3 or ou

## 2. TEST SITE LOCATION

#### 2.1 INTRODUCTION

The map at the right shows the location of the PCTEST LABORATORY in Columbia, Maryland. It is in proximity to the FCC Laboratory, the Baltimore-Washington International (BWI) airport, the city of Baltimore and Washington, DC (See Figure 2).

These measurement tests were conducted at the PCTEST Engineering Laboratory, Inc. facility in New Concept Business Park, Guilford Industrial Park, Columbia, Maryland. The site address is 6660-B Dobbin Road, Columbia, MD 21045. The test site is one of the highest points in the Columbia area with an elevation of 390 feet above mean sea level. The site coordinates are 39° 11'15" N latitude and 76° 49' 38" W longitude. The facility is 1.5 miles North of the FCC laboratory, and the ambient signal and ambient signal strength are approximately equal to those of the FCC laboratory. There are no FM or TV



Figure 2-1
Map of the Greater Baltimore and Metropolitan
Washington, D.C. area

transmitters within 15 miles of the site. The detailed description of the measurement facility was found to be in compliance with the requirements of § 2.948 according to ANSI C63.4 on January 27, 2006 and Industry Canada.

## 2.2 Test Facility / Accreditations:

Measurements were performed at an independent accredited PCTEST Engineering Lab located in Columbia, MD 21045, U.S.A.



- PCTEST Lab is accredited to ISO 17025-2005 by the American Association for Laboratory Accreditation (A2LA) in Specific Absorption Rate (SAR) testing, Hearing-Aid Compatibility (HAC), CTIA Test Plans, and wireless testing for FCC and Industry Canada Rules.
- PCTEST Lab is accredited to ISO 17025 by U.S. National Institute of Standards and Technology (NIST) under the National Voluntary Laboratory Accreditation Program (NVLAP Lab code: 100431-0) in EMC, FCC and Telecommunications.
- PCTEST facility is an FCC registered (PCTEST Reg. No. 90864) test facility with the site description report on file and has met all the requirements specified in Section 2.948 of the FCC Rules and Industry Canada (IC-2451).
- PCTEST Lab is a recognized U.S. Conformity Assessment Body (CAB) in EMC and R&TTE (n.b. 0982) under the U.S.-EU Mutual Recognition Agreement (MRA).



- PCTEST facility is an IC registered (IC-2451) test laboratory with the site description on file at Industry Canada.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for AMPS and CDMA, and EvDO mobile phones.
- PCTEST is a CTIA Authorized Test Laboratory (CATL) for Over-the-Air (OTA)
   Antenna Performance testing for AMPS, CDMA, GSM, GPRS, EGPRS, UMTS
   (W-CDMA), CDMA 1xEVDO Data, CDMA 1xRTT Data.

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 4 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		raye + 01 00



© 2012 PCTEST Engineering Laboratory, Inc.

## 3. **EUT DESCRIPTION**



FCC ID: A3LGTI9023

Manufacturer: Samsung Electronics Co., Ltd.

416 Maetan 3-Dong, Yeongtong-gu, Suwon-si

Gyeonggi-do, 443-742, Republic of Korea

Model(s): GT-I90 23

Serial Number: 144

Tx Frequencies Tested: 824.20 - 848.80 MHz (GSM 850)

1850.20 - 1909.80 MHz (GSM 1900) 1712.4 - 1752.5 MHz (AWS WCDMA)

Antenna Configurations: Internal Antenna

Maximum Tested Conducted Power 31.82 dBm (GSM 850), 29.84 dBm (GSM 1900),

(HAC): 22.26 dBm (AWS WDMA)

HAC Test Configurations: GSM 850, 128, 190, 251, BT Off, WLAN Off

GSM 1900, 512, 661, 810, BT Off, WLAN Off

AWS WCDMA, 1312, 1412, 1862, BT Off, WLAN Off

EUT Type: Portable Handset

Air-Interface	Band (MHz)	Туре	C63.19 tested	Simultaneous Transmissions (Not to be tested)	Reduced power 20.19 (c)(1)	Voice Over Digital Transport (Data)
	850	Voice	Vas	Yes: BT or WIFI	NI/A	N/A
GSM	1900	voice	165	Yes Yes: BT or WIFI N/A	IN/A	IN/A
	GPRS/EDGE	Data	N/A	Yes: BT or WIFI	N/A	Yes
WCDMA	1700	Voice	Yes	Yes: BT or WIFI	N/A	N/A
WCDIVIA	HSPA	Data	N/A	Yes: BT or WIFI	N/A	Yes
ВТ	2450	Data	N/A	Yes: GSM, WCDMA	N/A	N/A
WIFI	2450	Data	N/A	Yes: GSM, WCDMA	N/A	Yes

Table 3: A3LGTI9023 Air Interfaces

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 5 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		raye 3 01 00

## 4. ANSI/IEEE C63.19 PERFORMANCE CATEGORIES

## I. RF EMISSIONS

The ANSI Standard presents performance requirements for acceptable interoperability of hearing aids with wireless communications devices. When these parameters are met, a hearing aid operates acceptably in close proximity to a wireless communications device.

Category	Telephone RF Parameters				
Near field Category	E-field emissions CW dB(V/m)	H-field emissions CW dB(A/m)			
	f < 960 MHz				
M1	56 to 61 + 0.5 x AWF	5.6 to 10.6 +0.5 x AWF			
M2	51 to 56 + 0.5 x AWF	0.6 to 5.6 +0.5 x AWF			
M3	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF			
M4	< 46 + 0.5 x AWF < -4.4 + 0.5 x AWF				
	f > 960 MHz				
M1	46 to 51 + 0.5 x AWF	-4.4 to 0.6 +0.5 x AWF			
M2	41 to 46 + 0.5 x AWF	−9.4 to −4.4 +0.5 x AWF			
M3	36 to 41 + 0.5 x AWF	-14.4 to -9.4 +0.5 x AWF			
M4	< 36 + 0.5 x AWF	< -14.4 + 0.5 x AWF			
Table 4-1 Hearing aid and WD near-field categories as defined in ANSI C63.19-2007 [2]					

## **II. ARTICULATION WEIGHTING FACTOR (AWF)**

Standard	Technology	Articulation Weighing Factor (AWF)		
T1/T1P1/3GPP	UMTS (WCDMA)	0		
TIA/EIA/IS-2000	CDMA	0		
iDEN™	TDMA (22 and 11 Hz)	0		
J-STD-007	-5			
Table 4-2 Articulation Weighting Factors				

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 6 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 0 01 00

## 5. SYSTEM SPECIFICATIONS

#### **ER3DV6 E-Field Probe Description**

Construction: One dipole parallel, two dipoles normal to probe axis

Built-in shielding against static charges

Calibration: In air from 100 MHz to 3.0 GHz

(absolute accuracy ±6.0%, k=2)

Frequency: 100 MHz to > 6 GHz;

Linearity: ± 0.2 dB (100 MHz to 3 GHz)

Directivity  $\pm 0.2$  dB in air (rotation around probe axis)

± 0.4 dB in air (rotation normal to probe axis)

Dynamic Range 2 V/m to > 1000 V/m

(M3 or better device readings fall well below diode

compression point)

Linearity:  $\pm 0.2 \text{ dB}$ 

Dimensions Overall length: 330 mm (Tip: 16 mm)

Tip diameter: 8 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 2.5 mm



Figure 5-1 E-field Free-space Probe

#### **H3DV6 H-Field Probe Description**

Construction: Three concentric loop sensors with 3.8 mm loop diameters

Resistively loaded detector diodes for linear response

Built-in shielding against static charges

Frequency: 200 MHz to 3 GHz (absolute accuracy ± 6.0%, k=2);

Output linearized

Directivity:  $\pm 0.25$  dB (spherical isotropy error)

Dynamic Range: 10 mA/m to 2 A/m at 1 GHz

(M3 or better device readings fall well below diode

compression point)

Dimensions: Overall length: 330 mm (Tip: 40 mm)

Tip diameter: 6 mm (Body: 12 mm)

Distance from probe tip to dipole centers: 3 mm

E-Field < 10% at 3 GHz (for plane wave)

Interference:



**Figure 5-2** H-Field Free-space Probe

#### **Probe Tip Description**

HAC field measurements take place in the close near field with high gradients. Increasing the measuring distance from the source will generally decrease the measured field values (in case of the validation dipole approx. 10% per mm).

Magnetic field sensors are measuring the integral of the H-field across their sensor area surrounded by the loop. They are calibrated in a precise, homogeneous field. When measuring a gradient field, the result will be very close to the field in the center of the loop which is equivalent to the value of a homogeneous field equivalent to the center value. But it will be different from the field at the border of the loop.

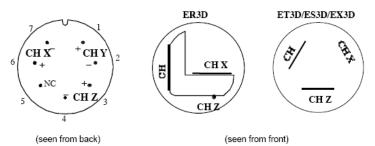
FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 7 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		raye / Ul OU

Consequently, two sensors with different loop diameters - both calibrated ideally - would give different results when measuring from the edge of the probe sensor elements. The behavior for electrically small E-field sensors is equivalent.

The magnetic field loops of the H3D probes are concentric, with the center 3mm from the tip for H3DV6. Their radius is 1.9mm.

The electric field probes have a more irregular internal geometry because it is physically not possible to have the 3 orthogonal sensors situated with the same center. The effect of the different sensor centers is accounted for in the HAC uncertainty budget ("sensor displacement"). Their geometric center is at 2.5mm from the tip, and the element ends are 1.1mm closer to the tip.

#### Connector Plan



The antistatic shielding inside the probe is connected to the probe connector case.

#### Instrumentation Chain

# Equation 1 Conversion of Connector Voltage $u_i$ to E-Field $E_i$

$$E_i = \sqrt{\frac{u_i + (u_i^2 \cdot CF)/(DCP)}{Norm_i \cdot ConvF}}$$

### whereby

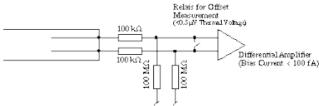
E<sub>i</sub>: electric field in V/m

 $u_i$ : voltage of channel i at the connector in  $\mu V$  $Norm_i$ : sensitivity of channel i in  $\mu V/(V/m)^2$ 

ConvF: enhancement factor in liquid (ConvF=1 for Air)
DCP: diode compression point in µV

DCP: diode compression point in μV
CF: signal crest factor (peak power/average power)

Conditions of Calibration



#### Please note:

- a lower input impedance of the amplifier will result in different sensitivity factors Norm, and DCP
- · larger bias currents will cause higher offset

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 8 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 0 01 00

## **Probe Response to Frequency**

The E-field sensors have inherently a very flat frequency response. They are calibrated with a number of frequencies resulting in a common calibration factor, with the frequency behavior documented in the calibration certificate (See also below).

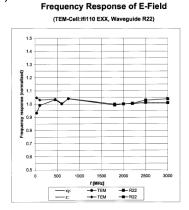


Figure 5-3 E-Field Probe Frequency Response

H-field sensors have a frequency dependent sensitivity which is evaluated for a series of frequencies also visible in the probe calibration certificate. The calibration factors result from a fitting algorithm. The proper conversion is calculated by the DASY software depending on the frequency setting in the procedure. See below for H-field frequency response:

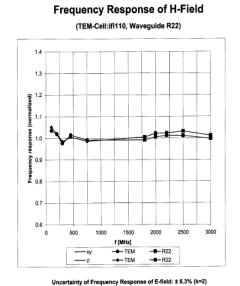


Figure 5-4 H-Field Probe Frequency Response

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 9 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 9 01 00

#### **Conversion to Peak**

Peak is defined as Peak Envelope Power. All raw measurements from the HAC measurement system are RMS values. The DASY system incorporates the crest factor of the signal in the computation of the RMS values (See Equation 1). Although the software also has capability to estimate the peak field by applying a square root of crest factor value to the readings, the probe modulation factor was applied manually instead per C63.19 in the measurement tables in this report. The equation to convert the raw measurements in the data tables are:

Peak Field = 20·log (Raw · PMF)

#### Where:

Peak Field = Peak field (in dBV/m or dBA/m)

Raw = Raw field measurement from the measurement system (in V/m or A/m).

PMF = Probe Modulation Factor (in linear units).

### **SPEAG Robotic System**

E-field and H-field measurements are performed using the DASY automated dosimetric assessment system. The DASY is made by Schmid & Partner Engineering AG (SPEAG) in Zurich, Switzerland and consists of high precision robotics system (Staubli), robot controller, Pentium 4 computer, near-field probe, probe alignment sensor, and the HAC phantom. The robot is a six-axis industrial robot performing precise movements to position the probe to the location (points) of maximum electromagnetic field (EMF).



**Figure 5-5** SPEAG Robotic System

#### **System Hardware**

A cell controller system contains the power supply, robot controller, teach pendant (Joystick), and a remote control used to drive the robot motors. The PC consists of the Gateway Pentium 4 2.53 GHz computer with Windows XP system and DASY RF Measurement Software (with HAC Extension), A/D interface card, monitor, mouse, and keyboard. The Staubli Robot is connected to the cell controller to allow software manipulation of the robot. A data acquisition electronic (DAE) circuit that performs the signal amplification, signal multiplexing, AD-conversion, offset measurements, mechanical surface detection, collision detection, etc. is connected to the Electro-optical coupler (EOC). The EOC performs the conversion from the optical into digital electric signal of the DAE and transfers data to the PC plug-in card.

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 10 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		raye 10 01 00

#### **System Electronics**

The DAE consists of a highly sensitive electrometer-grade preamplifier with auto-zeroing, a channel and gain-switching multiplexer, a fast 16 bit AD-converter and a command decoder and control logic unit. Transmission to the PC-card is accomplished through an optical downlink for data and status information and an optical uplink for commands and clock lines. The mechanical probe mounting device includes two different sensor systems for frontal and sidewise probe contacts. They are also used for mechanical surface detection and probe collision detection. The robot uses its own controller with a built in VME-bus computer.

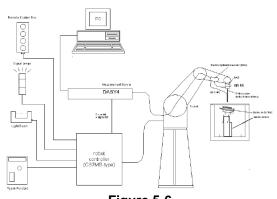


Figure 5-6 SPEAG Robotic System Diagram

#### **DASY Instrumentation Chain**

The first step of the evaluation is a linearization of the filtered input signal to account for the compression characteristics of the detector diode. The compensation depends on the input signal, the diode type and the DC-transmission factor from the diode to the evaluation electronics. If the exciting field is pulsed, the crest factor of the signal must be known to correctly compensate for peak power. The formula for each channel can be given as:

$$\begin{aligned} V_i &= U_i + U_i^2 \cdot \frac{cf}{dcp_i} \\ \text{with} \quad &V_i &= \text{compensated signal of channel i} & (i = x, y, z) \\ &U_i &= \text{input signal of channel i} & (i = x, y, z) \\ &cf &= \text{crest factor of exciting field} & (\text{DASY parameter}) \\ &dcp_i &= \text{diode compression point} & (\text{DASY parameter}) \end{aligned}$$

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPO	RT SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 11 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 11 01 00

From the compensated input signals the primary field data for each channel can be evaluated:

E – field  
probes : 
$$E_i = \sqrt{\frac{V_i}{Norm_i \cdot ConvF}}$$

$$\mbox{H} - \mbox{fieldprobes}: \qquad \ \ \, H_i = \sqrt{V_i} \cdot \frac{a_{i0} + a_{i1} f + a_{i2} f^2}{f}$$

with 
$$V_i$$
 = compensated signal of channel i (i = x, y, z  
 $Norm_i$  = sensor sensitivity of channel i (i = x, y, z

 $\mu V/(V/m)^2$  for E-field Probes

ConvF = sensitivity enhancement in solution

 $a_{ij}$  = sensor sensitivity factors for H-field probes

f = carrier frequency [GHz]

 $E_i$  = electric field strength of channel i in V/m  $H_i$  = magnetic field strength of channel i in A/m

The RSS value of the field components gives the total field strength (Hermitian magnitude):

$$E_{tot} = \sqrt{E_x^2 + E_y^2 + E_z^2}$$

The primary field data are used to calculate the derived field units.

The measurement/integration time per point, as specified by the system manufacturer is >500 ms.

The signal response time is evaluated as the time required by the system to reach 90% of the expected final value after an on/off switch of the power source with an integration time of 500 ms and a probe response time of <5 ms. In the current implementation, DASY waits longer than 100 ms after having reached the grid point before starting a measurement, i.e., the response time uncertainty is negligible.

If the device under test does not emit a CW signal, the integration time applied to measure the electric field at a specific point may introduce additional uncertainties due to the discretization. The tolerances for the different systems had the worst-case of 2.6%.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 12 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 12 01 00

## 6. TEST PROCEDURE

#### I. RF EMISSIONS

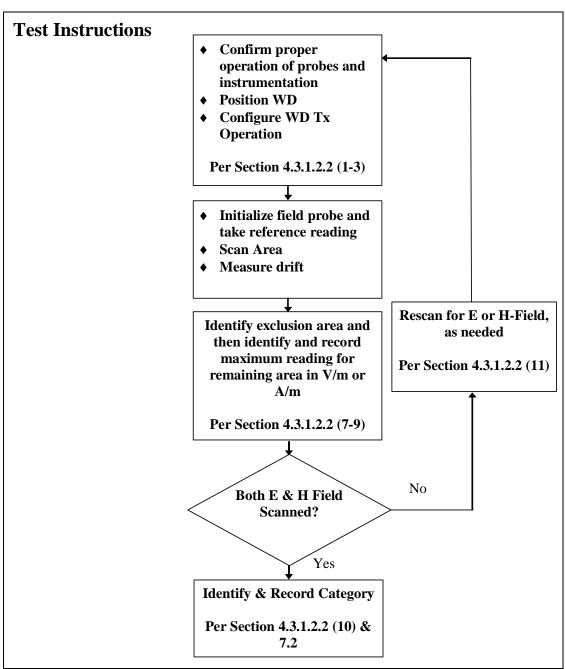


Figure 6-1 RF Emissions Flow Chart

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 13 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 13 01 60

## **Test Setup**

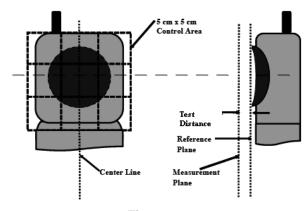


Figure 6-2
E/H-Field Emissions Test Setup Diagram (See Test Photographs for actual WD scan grid overlay)

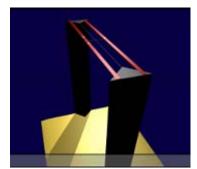


Figure 6-3 HAC Phantom

#### **RF Emissions Test Procedure:**

The following illustrate a typical RF emissions test scan over a wireless communications device:

- 1. Proper operation of the field probe, probe measurement system, other instrumentation, and the positioning system was confirmed.
- 2. WD is positioned in its intended test position, acoustic output point of the device perpendicular to the field probe.
- 3. The WD operation for maximum rated RF output power was configured and confirmed with the base station simulator, at the test channel and other normal operating parameters as intended for the test. The battery was ensured to be fully charged before each test.
- 4. The center sub-grid was centered over the center of the acoustic output (also audio band magnetic output, if applicable). The WD audio output was positioned tangent (as physically possible) to the measurement plane.
- 5. A surface calibration was performed before each setup change to ensure repeatable spacing and proper maintenance of the measurement plane using the HAC Phantom.
- 6. The measurement system measured the field strength at the reference location.
- 7. Measurements at 2mm or 5mm increments in the 5 x 5 cm region were performed at a distance 15 mm from the center point of the probe measurement element to the WD. A 360° rotation about the azimuth axis at the maximum interpolated position was measured. For the worst-case condition, the peak reading from this rotation was used in re-evaluating the HAC category.
- 8. The system performed a drift evaluation by measuring the field at the reference location.
- 9. Steps 1-8 were done for both the E and H-Field measurements.

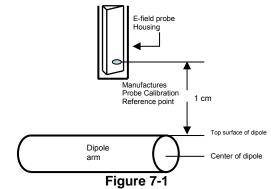
FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 14 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 14 01 00

## 7. SYSTEM CHECK

## I. System Check Parameters

The input signal was an un-modulated continuous wave. The following points were taken into consideration in performing this check:

- Average Input Power P = 100mW RMS (20dBm RMS) after adjustment for return loss
- The test fixture must meet the 2 wavelength separation criterion
- The proper measurement of the 1 cm probe to dipole separation, which is measured from top surface
  of the dipole to the calibration reference point of the sensor, defined by the probe manufacturer is
  shown in the following diagram:



Separation Distance from Dipole to Field Probe

RF power was recorded using both an average reading meter and a peak reading meter. Readings of the probe are provided by the measurement system.

To assure proper operation of the near-field measurement probe the input power to the dipole shall be commensurate with the full rated output power of the wireless device (e.g. - for a cellular phone wireless device the average peak antenna input power will be on the order of 100mW (i.e. - 20dBm) RMS after adjustment for any mismatch.

### **II. Validation Procedure**

A dipole antenna meeting the requirements given in C63.19 was placed in the position normally occupied by the WD.

The length of the dipole was scanned with both E-field and H-field probes and the maximum values for each were recorded.

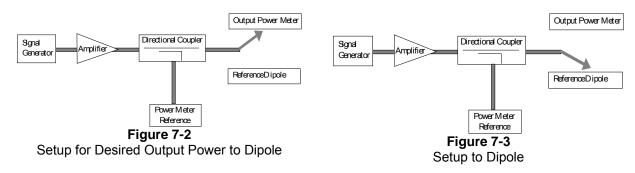
#### Measurement of CW

Using the near-field measurement system, scan the antenna over the radiating dipole and record the greatest field reading observed. Due to the nature of E-fields about free-space dipoles, the two E-field peaks measured over the dipole are averaged to compensate for non-parallelity of the setup (

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 15 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 13 01 00

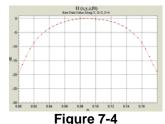
see manufacturer method on dipole calibration certificates, page 2). Field strength measurements shall be made only when the probe is stationary.

RF power was recorded using both an average and a peak power reading meter.

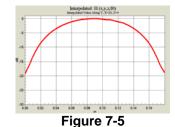


Using this setup configuration, the signal generator was adjusted for the desired output power (100mW) at a specified frequency. The reference power from the coupled port of the directional coupler is recorded. Next, the output cable is connected to the reference dipole, as shown in Figure 7-3.

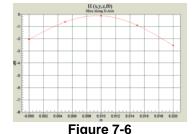
The input signal level was adjusted until the reference power from the coupled port of the directional coupler was the same as previously recorded, to compensate for the impedance mismatch between the output cable and the reference dipole. To assure proper operation of the near-field measurement probe the input power to the reference dipole was verified to the full rated output power of the wireless device. The dipole was secured in a holder in a manner to meet the 20 dB reflection. The near-field measurement probe was positioned over the dipole. The antenna was scanned over the appropriate sized area to cover the dipole from end to end. SPEAG uses 2D interpolation algorithms between the measured points. Please see below two dimensional plots showing that the interpolated values interpolate smoothly between 5mm steps for a free-space RF dipole:



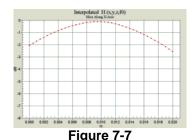
2-D Raw Data from scan along dipole axis



2-D Interpolated points from scan along dipole axis



2-D Raw Data from scan along transverse axis



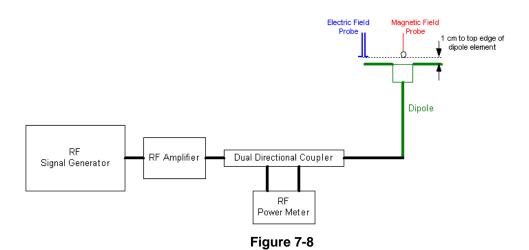
2-D Interpolated points from scan along transverse axis

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT			SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:		EUT Type:		Page 16 of 80
0Y1210311563.A3L	October 18-24, 2012		Portable Handset		Fage 10 01 00

## **III. System Check Results**

## **Validation Results**

Frequency (MHz)	Dipole S/N	Input Power (dBm)	E-field Result (V/m)	Target Field (V/m)	% Deviation
835	1003	20.0	158.1	166.0	-4.8%
1730	1137	20.0	146.6	151.5	-3.2%
1880	1137	20.0	141.3	136.8	3.3%
Frequency (MHz)	Dipole S/N	Input Power (dBm)	H-field Result (A/m)	Target Field (A/m)	% Deviation
	<b>Dipole S/N</b> 1003	Power	Result	Field	, ,
(MHz)	·	Power (dBm)	Result (A/m)	Field (A/m)	Deviation



FCC ID: A3LGTI9023

HAC (RF EMISSIONS) TEST REPORT

Quality Manager

Filename:
0Y1210311563.A3L

October 18-24, 2012

Portable Handset

Reviewed by:
Quality Manager

Page 17 of 80

System Check Setup

## 8. MODULATION FACTOR

A calibration was made of the modulation response of the probe and its instrumentation chain. This calibration was performed with the field probe, attached to its instrumentation. The response of the probe system to a CW field at the frequency of interest is compared to its response to a modulated signal with equal peak amplitude to that of a CW signal. The field level of the test signals are ensured to be more than 10 dB above the ambient level and the noise floor of the instrumentation being used. The ratio of the CW reading to that taken with a modulated reading was applied to the DUT measurements.

All voice modes for this device have been investigated in this section of the report. According to the FCC 3G Measurement Procedures, May 2006 for RF Emissions, variations in peak field and power readings.

### This was done using the following procedure:

- 1. The probe was illuminated with a CW signal at the intended measurement frequency and wireless device power.
- 2. The probe was positioned at the field maxima over the dipole antenna (determined after an area scan over the dipole) illuminated with the CW signal.
- 3. The reading of the probe measurement system of the CW signal at the maximum point was recorded.
- 4. Using a Spectrum Analyzer, the modulated signal adjusted with the same peak level of the CW signal was determined.
- 5. The probe measurement system reading was recorded with the modulated signal. The appropriate system crest factors for the modulation type were configured in the software to the system measurements.
- 6. The ratio of the CW reading to modulated signal reading is the probe modulation factor (PMF) for the modulation and field probe combination. This was repeated for 80% AM.
- 7. Steps 1-6 were repeated at all frequency bands and for both E and H field probes.

The modulation factors obtained were applied to readings taken of the actual wireless device, in order to obtain an accurate peak field reading using the formula:

Peak =  $20 \cdot \log (Raw \cdot PMF)$ 

#### **Modulation Factors:**

f (MHz)	Protocol	E-Field (V/m)	H-Field (A/m)	E-Field Modulation Factor	H-Field Modulation Factor						
835 835	AM GSM	629.3 287	2.212 1.033	1.290 2.829	0.910 1.948	f (MHz)	Protocol	E-Field (V/m)	H-Field	E-Field Modulation	H-Field Modulation
835	CW	811.8	2.012					(٧/١١)	(A/m)	Factor	Factor
1880	AM	390.8	1.215	1.319	1, 115	1730	AM	136.9	0.5584	1.449	1,222
1880	GSM	184.8	0.5843	2.790	2.319	1730	WCDMA	201.1	0.7426	0.986	0.919
1880	CW	515.6	1.355			1730	CW	198.3	0.6825		

Figure 8-1 Modulation Factors

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 18 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 10 01 00

#### Spectrum Analyzer Plots of ESG-D Signal used for PMF measurements:

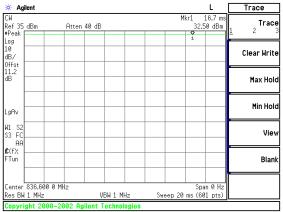


Figure 8-2 GSM850 CW Signal

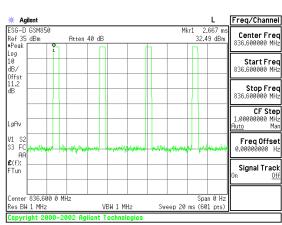


Figure 8-4 GSM850 Signal

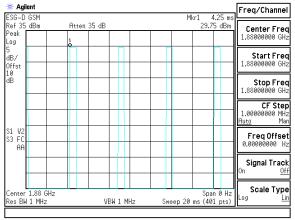


Figure 8-6 PCS GSM Signal

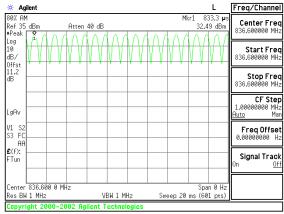


Figure 8-3 GSM850 80% AM Signal

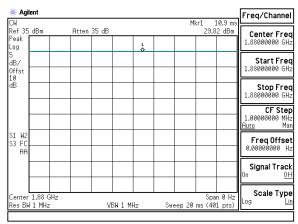


Figure 8-5 PCS CW Signal

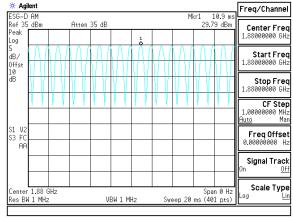


Figure 8-7 PCS 80% AM Signal

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 19 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 13 01 00

## 9. FCC 3G MEASUREMENT PROCEDURES

Power measurements were performed using a base station simulator under digital average power.

### I. Procedures Used to Establish RF Signal for HAC Testing

The handset was placed into a simulated call using a base station simulator in a shielded chamber. Such test signals offer a consistent means for testing HAC and are recommended for evaluating HAC. Measurements were taken with a fully charged battery. In order to verify that the device was tested and maintained at full power, this was configured with the base station simulator. The HAC measurement software calculates a reference point at the start and end of the test to check for power drifts. If conducted power deviations of more than 5% occurred, the tests were repeated.

#### II. HAC Measurement Conditions for WCDMA

#### **Output Power Verification**

Maximum output power is verified on the High, Middle and Low channels according to the general descriptions in section 5.2 of 3GPP TS 34.121, using the appropriate RMC or AMR with TPC (transmit power control) set to all "1s".

#### **HAC Measurements**

HAC is measured using the 12.2 kbps RMC with TPC bits configured to all "1s". HAC in AMR configurations is not required when the maximum average output of each RF channel for 12.2 kbps AMR is less than ¼ dB higher than that measured in 12.2 kbps RMC. Otherwise, HAC is measured on the maximum output channel in 12.2 AMR with a 3.4 kbps SRB (signaling radio bearer) using the configuration that results in the highest HAC for that RF channel in 12.2 RMC.

GSM RF	Conducted	Power Ta	ble		
Band	Channel	C	[dBm] S Slot)		
	128	31	.76		
Cellular	190	31	.82		
	251	31.78			
	512	29	.62		
PCS	661	29	29.64		
	810	29	29.84		
WCDMA R	F Conducte	d Power T	able		
3GPP 34.121 Subtest	AW	S Band [d	Bm]		
Subtest	1312	1412	1862		
12.2 kbps RMC	22.15	22.26	22.19		
12.2 kbps AMR	21.89	22.12	22.05		

Figure 9-1
Conducted Power Measurements for GT-I9023

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 20 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 20 01 00

## 10. OVERALL MEASUREMENT SUMMARY

FCC ID:	A3LGTI9023
Model:	GT-I9023
S/N:	144

## I. E-FIELD EMISSIONS:

Table 10-1
HAC Data Summary for E-field

	TIAO Data Gaillinai y Toi E-ficia												
Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4		
E-field Emissions													
GSM850	128	off	Acoustic	31.76	26.99	76.3	37.66	48.50	-10.84	M4	none		
GSM850	190	off	Acoustic	31.82	28.01	79.2	37.98	48.50	-10.52	M4	none		
GSM850	251	off	Acoustic	31.78	34.44	97.4	39.77	48.50	-8.73	M4	none		
GSM1900	512	off	Acoustic	29.62	23.99	66.9	36.51	38.50	-1.99	M3	1,2,3		
GSM1900	661	off	Acoustic	29.64	22.56	62.9	35.98	38.50	-2.52	M3	1,2,3		
GSM1900	810	off	Acoustic	29.84	25.40	70.9	37.01	38.50	-1.49	M3	1,2,3		

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (V/m)	Peak Field (V/m)	Peak Field (dBV/m)	FCC Limit (dBV/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
E-field Emissions											
AWS WCDMA	1312	off	Acoustic	22.15	25.88	25.5	28.1	41.0	-12.86	M4	none
AWS WCDMA	1412	off	Acoustic	22.26	28.68	28.3	29.0	41.0	-11.97	M4	none
AWS WCDMA	1862	off	Acoustic	22.19	32.01	31.6	30.0	41.0	-11.02	M4	none

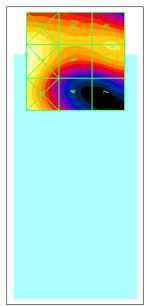


Figure 10-1
Sample E-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 21 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 21 01 00

FCC ID:	A3LGTI9023
Model:	GT-I9023
S/N:	144

## **II. H-FIELD EMISSIONS:**

Table 10-2 HAC Data Summary for H-field

	TIAO Data Guillinary for Ti-ficia												
Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4		
H-field Emissions													
GSM850	128	off	Acoustic	31.76	0.0703	0.137	-17.3	-1.9	-15.38	M4	none		
GSM850	190	off	Acoustic	31.82	0.0656	0.128	-17.9	-1.9	-15.98	M4	none		
GSM850	251	off	Acoustic	31.78	0.0636	0.124	-18.1	-1.9	-16.24	M4	none		
GSM1900	512	off	Acoustic	29.62	0.0929	0.216	-13.3	-11.9	-1.43	M3	none		
GSM1900	661	off	Acoustic	29.64	0.0830	0.192	-14.3	-11.9	-2.41	M3	none		
GSM1900	810	off	Acoustic	29.84	0.0930	0.216	-13.3	-11.9	-1.42	M3	none		

Mode	Channel	Backlight	Scan Center	Conducted Power at BS (dBm)	Time Avg. Field (A/m)	Peak Field (V/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT	Excl Blocks per 4.4
H-field Emissions											
AWS WCDMA	1312	off	Acoustic	22.15	0.0824	0.076	-22.4	-9.4	-13.01	M4	none
AWS WCDMA	1412	off	Acoustic	22.26	0.0885	0.081	-21.8	-9.4	-12.40	M4	none
AWS WCDMA	1862	off	Acoustic	22.19	0.0922	0.085	-21.4	-9.4	-12.04	M4	none

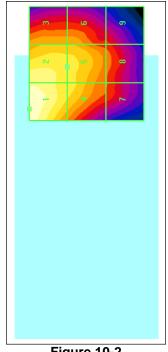


Figure 10-2
Sample H-field Scan Overlay
(See Test Setup Photographs for actual WD overlay)

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 22 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 22 01 00

FCC ID:	A3LGTI9023
Model:	GT-I9023
S/N:	144

## **III. Worst-case Configuration Evaluation**

Table 10-3
Peak Reading 360° Probe Rotation at Azimuth axis

Mode	Channel	Backlight	Scan Center	Time Avg. Field (A/m)	Peak Field (A/m)	Peak Field (dBA/m)	FCC Limit (dBA/m)	FCC MARGIN (dB)	RESULT
Probe Rotat	Probe Rotation at Worst-Case								
GSM1900	810	off	Acoustic	0.0930	0.2	-13.3	-11.90	-1.42	M3

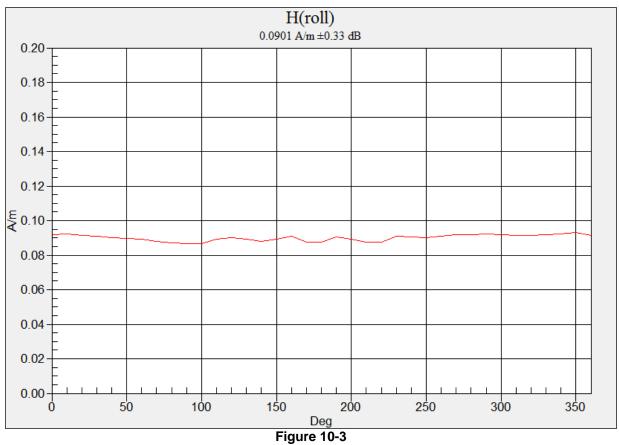


Figure 10-3
Worst-Case Probe Rotation about Azimuth axis

\* Note: Locations of probe rotation (with and without exclusions) are shown in Figure 10-1 or Figure 10-2 denoted by the green square markers.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 23 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 23 01 60

## 11. EQUIPMENT LIST

Manufacturer	Model	Description	Cal Date	Cal Interval	Cal Due	Serial Number
Rohde & Schwarz	CMU200	Base Station Simulator	5/22/2012	Annual	5/22/2013	109892
SPEAG	DAE4	Dasy Data Acquisition Electronics	5/15/2012	Annual	5/15/2013	859
Rohde & Schwarz	NRVD	Dual Channel Power Meter	4/8/2011	Biennial	4/8/2013	101695
Agilent E4	407B	ESA Spectrum Analyzer 4	/3/2012	Annual 4	/3/2013	US39210313
Agilent	E4432B	ESG-D Series Signal Generator	3/15/2012	Annual	3/15/2013	US40053896
SPEAG	CD1880V3	Freespace 1880 MHz Dipole	2/9/2011	Biennial	2/9/2013	1137
SPEAG	CD835V3 F	reespace 835 MHz Dipole 2	/8/2011	Biennial	2/8/2013	1003
SPEAG ER	3DV6	Freespace E-field Probe	8/23/2012	Annual	8/23/2013	2335
SPEAG H3	DV6	Freespace H-field Probe	8/23/2012	Annual	8/23/2013	6170
Mini-Circuits	NLP-1200+	Low Pass Filter DC to 1000 MHz	N/A	CBT*	N/A	N/A
Mini-Circuits	NLP-2950+	Low Pass Filter DC to 2700 MHz	N/A	CBT*	N/A	N/A
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (100uW-2W)	10/11/2012	Biennial	10/11/2014	100155
Rohde & Schwarz	NRV-Z32	Peak Power Sensor (1mW-20W) 10	/11/2012	Annual	10/11/2013	100004
Mini-Circuits BW	- N20W5	Power Attenuator	N/A	CBT*	NA	1226
Anritsu M	L2438A	Power Meter	2/14/2012	Annual	2/14/2013	1190013
Anritsu M	L2438A	Power Meter	2/14/2012	Annual	2/14/2013	98150041
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	5318
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	5442
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	5821
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	8013
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	2400
Anritsu M	A2481A	Power Sensor	2/14/2012	Annual	2/14/2013	3681
Anritsu	MA2481A P	ower Sensor 4	/5/2012	Annual	4/5/2013	5605
Rohde & Schwarz	SME06	Signal Generator	10/10/2012	Annual	10/10/2013	832026
Seekonk N	C-100	Torque Wrench (8" lb) 11	/29/2011	Triennial	11/29/2014	21053
Anritsu M	A24106A	USB Power Sensor	8/22/2012	Annual	8/22/2013	1231538
Anritsu M	A24106A	USB Power Sensor	8/22/2012	Annual	8/22/2013	1231535
Control Company	36934-158	Wall-Mounted Thermometer	1/4/2012	Biennial	1/4/2014	122014497
Control Company 3	6934-158	Wall-Mounted Thermometer	1/4/2012	Biennial 1/	4/2014	122014488
Agilent	E5515C	Wireless Communications Test Set	2/9/2012	Annual 2	/9/2013	GB43460554
Agilent	E5515C	Wireless Communications Test Set	2/12/2012	Annual	2/12/2013	GB45360985
Agilent	E5515C	Wireless Communications Test Set	2/14/2012	Annual	2/14/2013	GB43304447
Agilent	E5515C	Wireless Communications Test Set	9/24/2012	Annual	9/24/2013	GB43163447
Agilent	E5515C	Wireless Communications Test Set	4/4/2012	Annual 4	/4/2013	US41140256

## Table 11-1 Equipment List

Calibration traceable to the National Institute of Standards and Technology (NIST).

\* Note: CBT (Calibrated Before Testing). Prior to testing, the measurement paths containing a cable, attenuator, coupler or filter were connected to a calibrated source (i.e. a signal generator) to determine the losses of the measurement path. The power meter offset was then adjusted to compensate for the measurement system losses. This level offset is stored within the power meter before measurements are made. This calibration verification procedure applies to the system verification and output power measurements. The calibrated reading is then taken directly from the power meter after compensation of the losses for all final power measurements.

FCC ID: A3LGTI9023	PCTEST*	PCTEST HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 24 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 24 01 00

## 12. MEASUREMENT UNCERTAINTY

Wireless Communications Device Near-Field Measurement									
	Uncertainty Estimation								
Uncertainty Component	Data (dB)	Data Type	Prob. Dist.	Divisor	Ci (E)	Ci (H)	Unc. (dB)	Notes/Comment s	
Measurement System									
RF System Reflections	0.50	Tolerance	N	1.00	1	1	0.50	Refl. < -20 dB	
Field Probe Calibration	0.21	Tolerance	N	1.00	1	1	0.21		
Field Probe Isotropy	0.01	Tolerance	N	1.00	1	1	0.01		
Field Probe Frequency Response	0.135	Tolerance	N	1.00	1	1	0.14		
Field Probe Linearity	0.013	Tolerance	N	1.00	1	1	0.01		
Probe Modulation Factor	0.270	Accuracy	R	1.73	1	1	0.16		
Boundary Effects	0.105	Accuracy	R	1.73	1	1	0.06	*	
Probe Positioning Accuracy	0.20	Accuracy	R	1.73	1	0.670	0.12	*	
Probe Positioner	0.050	Accuracy	R	1.73	1	0.670	0.03	*	
Extrapolation/Interpolation	0.045	Tolerance	R	1.73	1	1	0.03	*	
Resolution to 2mm error	0.210	Tolerance	N	1.00	1	1	0.21		
System Detection Limit	0.05	Tolerance	R	1.73	1	1	0.03	*	
Readout Electronics	0.015	Tolerance	N	1.00	1	1	0.02	*	
Integration Time	0.11	Tolerance	R	1.73	1	1	0.06	*	
Response Time	0.033	Tolerance	R	1.73	1	1	0.02	*	
Phantom Thickness	0.10	Tolerance	R	1.73	1	1	0.06	*	
System Repeatability (Field x 2=power)	0.17	Tolerance	N	1.00	1	1	0.17		
Test Sample Related		•	•		•		•		
Device Positioning Vertical	0.2	Tolerance	R	1.73	- 1	1	0.12	*	
Device Positioning Lateral	0.045	Tolerance	R	1.73	1	1	0.03	*	
Device Holder and Phantom	0.1	Tolerance	R	1.73	1	1	0.06	*	
Power Drift	0.21	Tolerance	R	1.73	1	1	0.12		
Combined Standard Uncertainty (k=1)							0.66	16.5%	
Expanded Uncertainty [95% confidence] (k=2)							1.33	32.3%	
Expanded Uncertainty [95% confidence] on Field							0.66	16.2%	

# Table 12-1 Uncertainty Estimation Table

#### Notes:

- Test equipments are calibrated according to techniques outlined in NIS81, NIS3003 and NIST Tech Note 1297. All
  equipments have traceability according to NIST. Measurement Uncertainties are defined in further detail in NIS 81
  and NIST Tech Note 1297 and UKAS M3003.
- 2. \* Uncertainty specifications from Schmidt & Partner Engineering AG (not site specific)

Measurement uncertainty reflects the quality and accuracy of a measured result as compared to the true value. Such statements are generally required when stating results of measurements so that it is clear to the intended audience that the results may differ when reproduced by different facilities. Measurement results vary due to the measurement uncertainty of the instrumentation, measurement technique, and test engineer. Most uncertainties are calculated using the tolerances of the instrumentation used in the measurement, the measurement setup variability, and the technique used in performing the test. While not generally included, the variability of the equipment under test also figures into the overall measurement uncertainty. Another component of the overall uncertainty is based on the variability of repeated measurements (so-called Type A uncertainty). This may mean that the Hearing Aid immunity tests may have to be repeated by taking down the test setup and resetting it up so that there are a statistically significant number of repeat measurements to identify the measurement uncertainty. By combining the repeat measurement results with that of the instrumentation chain using the technique contained in NIS 81 and NIS 3003, the overall measurement uncertainty was estimated.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 25 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 23 01 60

## 13. TEST DATA

See following Attached Pages for Test Data.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 26 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 20 01 00



## DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

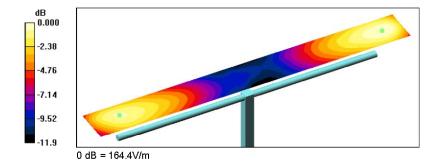
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

#### 835 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 107.7 V/m; Power Drift = 0.151 dB
Average value of Peak (interpolated) = 158.1 V/m



FCC ID: A3LGTI9023	PCTEST	CTEST HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 27 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 21 01 00



## DUT: CD835V3 - SN1003

Type: CD835V3 Serial: 1003

Communication System: CW; Frequency: 835 MHz;

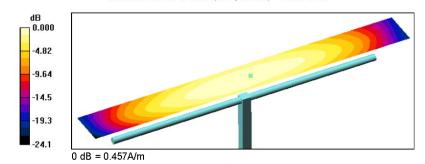
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## 835 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.474 A/m; Power Drift = 0.106 dB
Maximum value of Total (interpolated) = 0.457 A/m



FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 28 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 20 01 00



## DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1730 MHz;

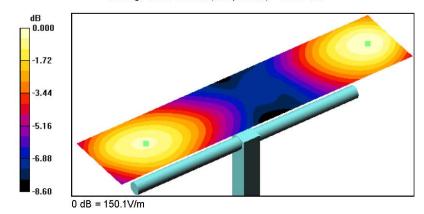
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## 1730 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 168.7 V/m; Power Drift = 0.124 dB
Average value of Peak (interpolated) = 146.6 V/m



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		T REPORT	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 29 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 23 01 00



## DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1730 MHz;

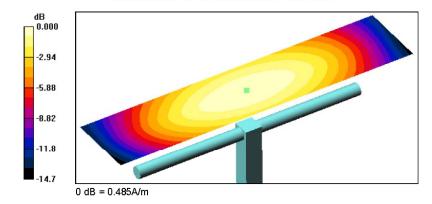
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## 1730 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm Probe Modulation Factor = 1.00 Device Reference Point: 0.000, 0.000, -6.30 mm Reference Value = 0.508 A/m; Power Drift = 0.033 dB Maximum value of Total (interpolated) = 0.485 A/m



FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 30 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 30 01 60



## DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

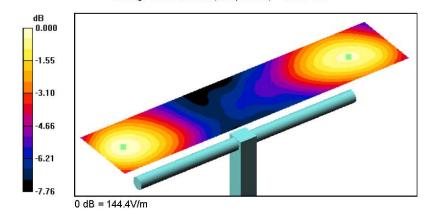
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## 1880 MHz / 100mW HAC Dipole Validation at 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 162.4 V/m; Power Drift = 0.132 dB
Average value of Peak (interpolated) = 141.3 V/m



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 31 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 31 01 00



## DUT: CD1880V3 - SN1137

Type: CD1880V3 Serial: 1137

Communication System: CW; Frequency: 1880 MHz;

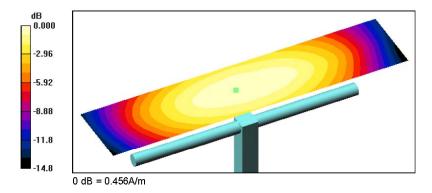
Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: 0mm (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## 1880 MHz / 100 mW HAC Validation at 10 mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm
Probe Modulation Factor = 1.00
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.480 A/m; Power Drift = -0.017 dB
Maximum value of Total (interpolated) = 0.456 A/m



FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 32 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 32 01 60

Date: 10/24/2012



## DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 848.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

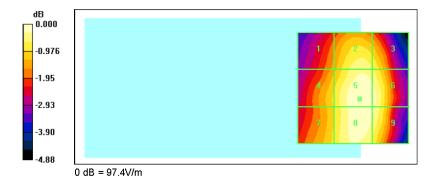
- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## GSM850 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 97.4 V/m
Probe Modulation Factor = 2.829
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 44.1 V/m; Power Drift = -0.036 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

#### Peak E-field in V/m

		Grid 3
82.8 M4	93.0 M4	91.3 M4
		Grid 6
87.9 M4	97.4 M4	95.8 M4
		<b>95.8 M4</b> Grid 9



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager	
Filename:	Test Dates:	EUT Type:		Page 33 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 33 01 60

Date: 10/23/2012



## DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 824.2 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

## DASY5 Configuration:

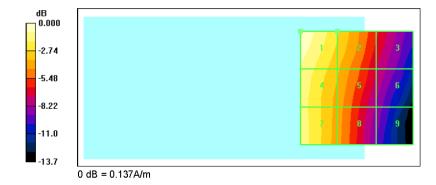
- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

#### GSM850 Low Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.137 A/m
Probe Modulation Factor = 1.948
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.036 A/m; Power Drift = 0.183 dB
Hearing Aid Near-Field Category: M4 (AWF -5 dB)

#### Peak H-field in A/m

		Grid 3
0.137 M4	0.101 M4	0.068 M4
		Grid 6
0.123 M4	0.092 M4	0.060 M4
Grid 7	Grid 8	Grid 9
		0.053 M4



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager	
Filename:	Test Dates:	EUT Type:		Page 34 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 34 01 60

Date: 10/24/2012



## DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:8.3

#### Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

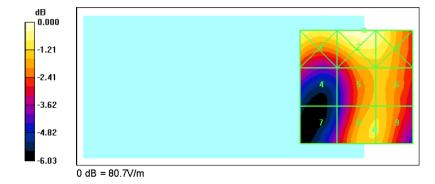
- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## GSM1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 70.9 V/m
Probe Modulation Factor = 2.790
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 27.5 V/m; Power Drift = -0.199 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

#### Peak E-field in V/m

		Grid 3
77.7 M3	80.7 M3	78.1 M3
		Grid 6
58.5 M3	68.8 M3	69.0 M3
	Grid 8	Grid 9



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager	
Filename:	Test Dates:	EUT Type:		Page 35 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 33 01 60

Date: 10/24/2012



## DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:8.3

Communication System: GSM; Frequency: 1909.8 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

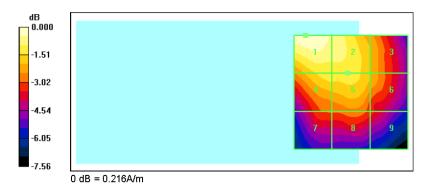
- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

## GSM1900 High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.216 A/m
Probe Modulation Factor = 2.319
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.085 A/m; Power Drift = -0.195 dB
Hearing Aid Near-Field Category: M3 (AWF -5 dB)

#### Peak H-field in A/m

		Grid 3
0.216 M3	0.202 M3	0.172 M3
		Grid 6
0.186 M3	0.187 M3	0.172 M3
		Grid 9
0.154 M3	0.159 M3	0.148 M3



FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager	
Filename:	Test Dates:	EUT Type:		Page 36 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 30 01 60

Date: 10/24/2012



#### DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1752.5 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

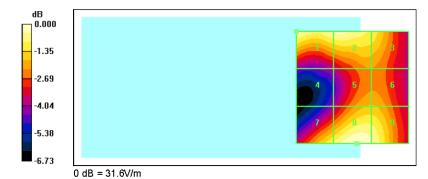
- Probe: ER3DV6 SN2335; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

#### AWS WCDMA High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 31.6 V/m
Probe Modulation Factor = 0.986
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 28.9 V/m; Power Drift = -0.057 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak E-field in V/m

		Grid 3
31.0 M4	30.5 M4	28.3 M4
		Grid 6
20.5 M4	26 N M/	26 O M/
20.5 1914	20.0 1014	20.0 1014
	Grid 8	Grid 9



#### 2012 PCTEST

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 37 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 37 01 00

Date: 10/24/2012



#### DUT: A3LGTI9023

Type: Portable Handset Serial: 144 Backlight off Duty Cycle: 1:1

Communication System: WCDMA; Frequency: 1752.5 MHz;

Measurement Standard: DASY5 (High Precision Assessment)

#### DASY5 Configuration:

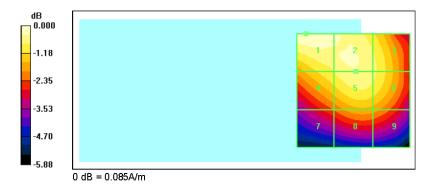
- Probe: H3DV6 SN6170; Calibrated: 8/23/2012
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn859; Calibrated: 5/15/2012
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA;
- Measurement SW: DASY52, V52.8 Build 1;

#### AWS WCDMA High Channel/Hearing Aid Compatibility Test (101x101x1):

Measurement grid: dx=5mm, dy=5mm
Maximum value of peak Total field = 0.085 A/m
Probe Modulation Factor = 0.919
Device Reference Point: 0.000, 0.000, -6.30 mm
Reference Value = 0.093 A/m; Power Drift = -0.061 dB
Hearing Aid Near-Field Category: M4 (AWF 0 dB)

#### Peak H-field in A/m

		Grid 3
0.085 M4	0.083 M4	0.079 M4
		Grid 6
0.078 M4	0.081 M4	0.079 M4
		Grid 9
0.065 M4	0.070 M4	0.069 M4



#### 2012 PCTEST

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 38 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 30 01 60

### 14. CALIBRATION CERTIFICATES

The following pages include the probe calibration used to evaluate HAC for the DUT.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 39 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 39 01 00

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

**PC Test** 

Certificate No: ER3-2335\_Aug12

Accreditation No.: SCS 108

#### **CALIBRATION CERTIFICATE**

Object

ER3DV6 - SN:2335

Calibration procedure(s)

QA CAL-02.v6, QA CAL-25.v4

Calibration procedure for E-field probes optimized for close near field

evaluations in air

Calibration date:

August 23, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI).

The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	D	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	29-Mar-12 (No. 217-01508)	Apr-13
Power sensor E4412A	MY41498087	29-Mar-12 (No. 217-01508)	Apr-13
Reference 3 dB Attenuator	SN: S5054 (3c)	27-Mar-12 (No. 217-01531)	Apr-13
Reference 20 dB Attenuator	SN: S5086 (20b)	27-Mar-12 (No. 217-01529)	Apr-13
Reference 30 dB Attenuator	SN: S5129 (30b)	27-Mar-12 (No. 217-01532)	Apr-13
Reference Probe ER3DV6	SN: 2328	11-Oct-11 (No. ER3-2328_Oct11)	Oct-12
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Name Function
Calibrated by: Jeton Kastrati Laboratory Technician

Approved by:

Katja Pokovic Technical Manager

Issued: August 24, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: ER3-2335\_Aug12

Page 1 of 10

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 40 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 40 01 00

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst S Service suisse d'étalonnage C Servizio svizzero di taratura S Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS) The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossarv:

CF

NORMx,y,z sensitivity in free space DCP diode compression point

crest factor (1/duty\_cycle) of the RF signal A, B, C modulation dependent linearization parameters

Polarization  $\phi$ φ rotation around probe axis

9 rotation around an axis that is in the plane normal to probe axis (at measurement center), Polarization 9

i.e.,  $\vartheta = 0$  is normal to probe axis

Connector Angle information used in DASY system to align probe sensor X to the robot coordinate system

#### Calibration is Performed According to the Following Standards:

iEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005

b) CTIA Test Plan for Hearing Aid Compatibility, April 2010.

#### Methods Applied and Interpretation of Parameters:

- NORMx, y, z: Assessed for E-field polarization  $\vartheta = 0$  for XY sensors and  $\vartheta = 90$  for Z sensor (f  $\leq 900$  MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- $NORM(f)x,y,z = NORMx,y,z * frequency_response$  (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open wavequide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the NORMx (no uncertainty required).

Certificate No: ER3-2335\_Aug12

Page 2 of 10

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 41 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 41 01 00

ER3DV6 – SN:2335 August 23, 2012

# Probe ER3DV6

SN:2335

Manufactured: Calibrated:

September 9, 2003 August 23, 2012

Calibrated for DASY/EASY Systems

(Note: non-compatible with DASY2 system!)

Certificate No: ER3-2335\_Aug12

Page 3 of 10

FCC ID: A3LGTI9023	PCTEST'	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 42 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 42 01 60

ER3DV6-SN:2335 August 23, 2012

### DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

#### **Basic Calibration Parameters**

	Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm (µV/(V/m) <sup>2</sup> )	1.67	1.67	1.87	± 10.1 %
DCP (mV) <sup>B</sup>	98.7	99.4	99.4	

**Modulation Calibration Parameters** 

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc <sup>E</sup> (k=2)
0	CW	0.00	Х	0.00	0.00	1.00	165.4	±3.0 %
			Y	0.00	0.00	1.00	211.0	
			Z	0.00	0.00	1.00	205.1	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

Certificate No: ER3-2335\_Aug12

Page 4 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 43 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 43 01 00

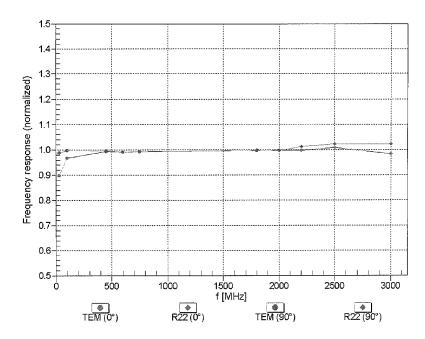
B Numerical linearization parameter: uncertainty not required.

E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

ER3DV6-SN:2335

August 23, 2012

## Frequency Response of E-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of E-field: ± 6.3% (k=2)

Certificate No: ER3-2335\_Aug12

Page 5 of 10

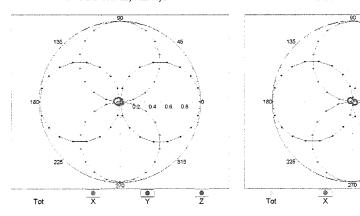
FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 44 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 44 01 00

ER3DV6- SN:2335 August 23, 2012

### Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

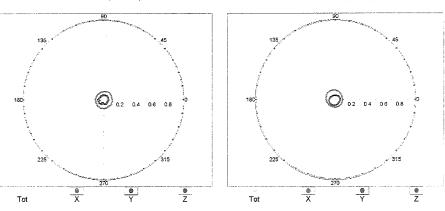
f=2500 MHz,R22,0°



### Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$

f=600 MHz,TEM,90°

f=2500 MHz,R22,90°



Certificate No: ER3-2335\_Aug12

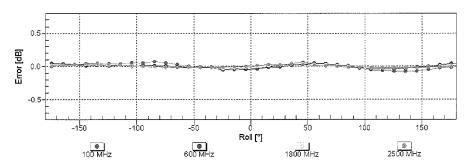
Page 6 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 45 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 45 01 00

ER3DV6-SN:2335

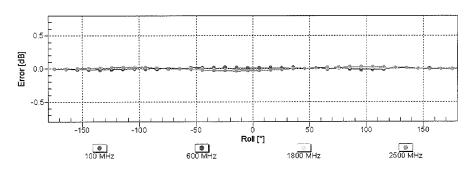
August 23, 2012

### Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

### Receiving Pattern ( $\phi$ ), $\vartheta = 90^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

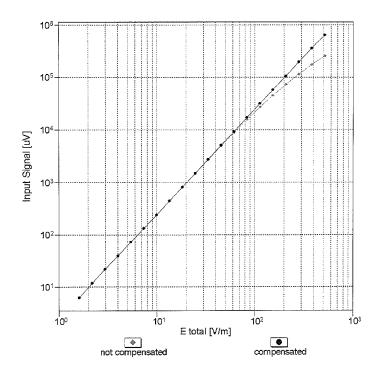
Certificate No: ER3-2335\_Aug12

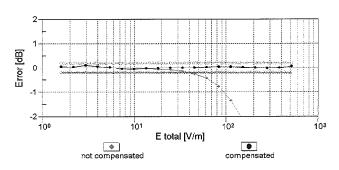
Page 7 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 46 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 40 01 00

ER3DV6-SN:2335 August 23, 2012

# Dynamic Range f(E-field) (TEM cell , f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

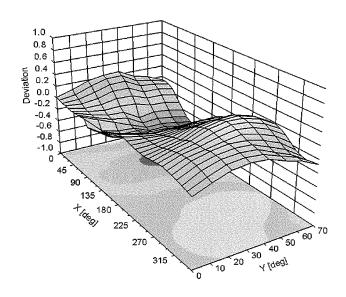
Certificate No: ER3-2335\_Aug12

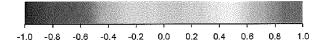
Page 8 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 47 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 47 01 00

August 23, 2012 ER3DV6-SN:2335

# Deviation from Isotropy in Air Error (ø, 9), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

Certificate No: ER3-2335\_Aug12

Page 9 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 48 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 40 01 00

ER3DV6- SN:2335 August 23, 2012

### DASY/EASY - Parameters of Probe: ER3DV6 - SN:2335

#### **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	85.6
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	10 mm
Tip Diameter	8 mm
Probe Tip to Sensor X Calibration Point	2.5 mm
Probe Tip to Sensor Y Calibration Point	2.5 mm
Probe Tip to Sensor Z Calibration Point	2.5 mm

Certificate No: ER3-2335\_Aug12

Page 10 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 49 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 43 01 00

Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Client

**PC Test** 

Certificate No: H3-6170\_Aug12

#### **CALIBRATION CERTIFICATE**

Object

H3DV6 - SN:6170

Calibration procedure(s)

QA CAL-03.v6, QA CAL-25.v4

Calibration procedure for H-field probes optimized for close near field

evaluations in air

Calibration date:

August 23, 2012

This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). The measurements and the uncertainties with confidence probability are given on the following pages and are part of the certificate.

All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%.

Calibration Equipment used (M&TE critical for calibration)

Primary Standards	ID	Cal Date (Certificate No.)	Scheduled Calibration
Power meter E4419B	GB41293874	29-Mar-12 (No. 217-01508)	Apr-13
Power sensor E4412A	MY41498087	29-Mar-12 (No. 217-01508)	Apr-13
Reference 3 dB Attenuator	SN: S5054 (3c)	27-Mar-12 (No. 217-01531)	Apr-13
Reference 20 dB Attenuator	SN: S5086 (20b)	27-Mar-12 (No. 217-01529)	Apr-13
Reference 30 dB Attenuator	SN: S5129 (30b)	27-Mar-12 (No. 217-01532)	Apr-13
Reference Probe H3DV6	SN: 6182	11-Oct-11 (No. H3-6182_Oct11)	Oct-12
DAE4	SN: 789	30-Jan-12 (No. DAE4-789_Jan12)	Jan-13
Secondary Standards	ID	Check Date (in house)	Scheduled Check
RF generator HP 8648C	US3642U01700	4-Aug-99 (in house check Apr-11)	In house check: Apr-13
Network Analyzer HP 8753E	US37390585	18-Oct-01 (in house check Oct-11)	In house check: Oct-12

Calibrated by:

Name
Function
Signature

Laboratory Technician

Approved by:

Katja Pokovic
Technical Manager

Issued: August 24, 2012

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: H3-6170\_Aug12

Page 1 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 50 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 30 01 60

#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA Multilateral Agreement for the recognition of calibration certificates

Glossary:

NORMx,y,z DCP sensitivity in free space diode compression point

CF

crest factor (1/duty\_cycle) of the RF signal

A, B, C

modulation dependent linearization parameters

Polarization φ

φ rotation around probe axis

Polarization 9

9 rotation around an axis that is in the plane normal to probe axis (at measurement center),

i.e.,  $\vartheta = 0$  is normal to probe axis

Connector Angle

information used in DASY system to align probe sensor X to the robot coordinate system

#### Calibration is Performed According to the Following Standards:

- a) IEEE Std 1309-2005, "IEEE Standard for calibration of electromagnetic field sensors and probes, excluding antennas, from 9 kHz to 40 GHz", December 2005.
- b) CTIA Test Plan for Hearing Aid Compatibility, April 2010.

#### Methods Applied and Interpretation of Parameters:

- NORMx,y,z: Assessed for E-field polarization θ = 0 for XY sensors and θ = 90 for Z sensor (f ≤ 900 MHz in TEM-cell; f > 1800 MHz: R22 waveguide).
- X,Y,Z(f)\_a0a1a2= X,Y,Z\_a0a1a2\* frequency\_response (see Frequency Response Chart).
- DCPx,y,z: DCP are numerical linearization parameters assessed based on the data of power sweep with CW signal (no uncertainty required). DCP does not depend on frequency nor media.
- PAR: PAR is the Peak to Average Ratio that is not calibrated but determined based on the signal characteristics
- Ax,y,z; Bx,y,z; Cx,y,z, VRx,y,z: A, B, C are numerical linearization parameters assessed based on the data of
  power sweep for specific modulation signal. The parameters do not depend on frequency nor media. VR is the
  maximum calibration range expressed in RMS voltage across the diode.
- Spherical isotropy (3D deviation from isotropy): in a locally homogeneous field realized using an open waveguide setup.
- Sensor Offset: The sensor offset corresponds to the offset of virtual measurement center from the probe tip (on probe axis). No tolerance required.
- Connector Angle: The angle is assessed using the information gained by determining the X\_a0a1a2 (no
  uncertainty required).

Certificate No: H3-6170\_Aug12

Page 2 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 51 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 31 01 60

H3DV6 – SN:6170 August 23, 2012

# Probe H3DV6

SN:6170

Manufactured: Calibrated:

May 19, 2005 August 23, 2012

Calibrated for DASY/EASY Systems

(Note: non-compatible with DASY2 system!)

Certificate No: H3-6170\_Aug12

Page 3 of 10

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 52 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 52 01 60

August 23, 2012 H3DV6-SN:6170

### DASY/EASY - Parameters of Probe: H3DV6 - SN:6170

**Basic Calibration Parameters** 

		Sensor X	Sensor Y	Sensor Z	Unc (k=2)
Norm $(A/m / \sqrt{(mV)})$	a0	2.54E-003	2.70E-003	3.01E-003	± 5.1 %
Norm $(A/m / \sqrt{(mV)})$	a1	1.06E-004	-4.47E-005	-1.18E-004	± 5.1 %
Norm $(A/m / \sqrt{(mV)})$	a2	1.49E-005	-1.46E-005	4.49E-005	± 5.1 %
DCP (mV) <sup>B</sup>		96.6	91.6	91.6	

**Modulation Calibration Parameters** 

UID	Communication System Name	PAR		A dB	B dB	C dB	VR mV	Unc <sup>t</sup> (k=2)
0	CW	0.00	X	0.00	0.00	1.00	134.4	±3.0 %
			Y	0.00	0.00	1.00	132.5	
Harrison III			Z	0.00	0.00	1.00	137.9	

The reported uncertainty of measurement is stated as the standard uncertainty of measurement multiplied by the coverage factor k=2, which for a normal distribution corresponds to a coverage probability of approximately 95%.

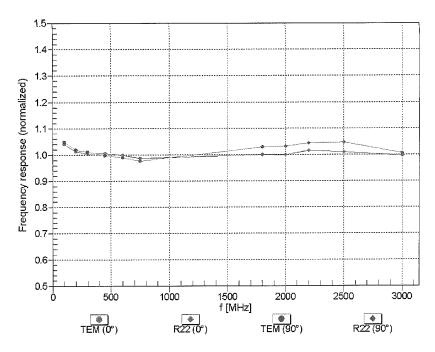
Certificate No: H3-6170\_Aug12

Page 4 of 10

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 53 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 33 01 60

B Numerical linearization parameter: uncertainty not required.
E Uncertainty is determined using the max. deviation from linear response applying rectangular distribution and is expressed for the square of the field value.

# Frequency Response of H-Field (TEM-Cell:ifi110 EXX, Waveguide: R22)



Uncertainty of Frequency Response of H-field: ± 6.3% (k=2)

Certificate No: H3-6170\_Aug12

Page 5 of 10

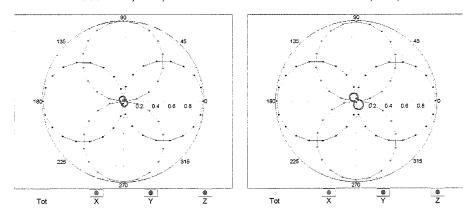
FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 54 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 34 01 00

H3DV6- SN:6170 August 23, 2012

### Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$

f=600 MHz,TEM,0°

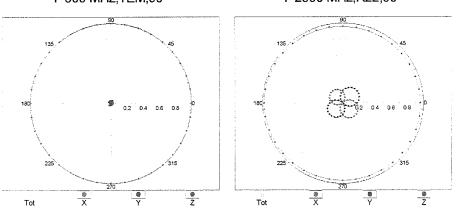
f=2500 MHz,R22,0°



### Receiving Pattern ( $\phi$ ), $9 = 90^{\circ}$

f=600 MHz,TEM,90°

f=2500 MHz,R22,90°



Certificate No: H3-6170\_Aug12

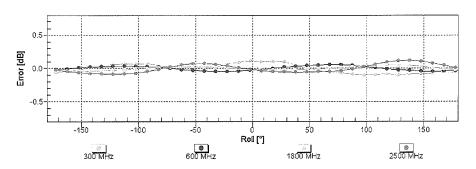
Page 6 of 10

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 55 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 33 01 60

H3DV6- SN:6170

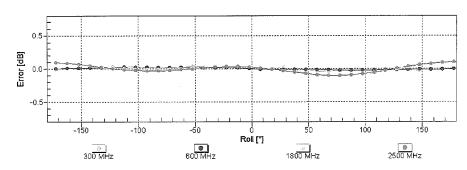
August 23, 2012

### Receiving Pattern ( $\phi$ ), $\vartheta = 0^{\circ}$



Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

### Receiving Pattern ( $\phi$ ), $9 = 90^{\circ}$



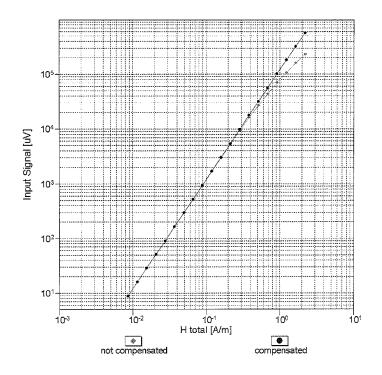
Uncertainty of Axial Isotropy Assessment: ± 0.5% (k=2)

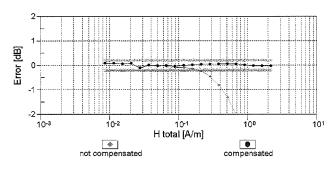
Certificate No: H3-6170\_Aug12

Page 7 of 10

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 56 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 30 01 60

# Dynamic Range f(H-field) (TEM cell, f = 900 MHz)





Uncertainty of Linearity Assessment: ± 0.6% (k=2)

Certificate No: H3-6170\_Aug12

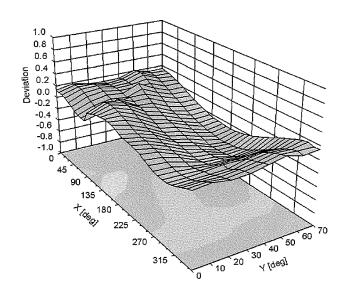
Page 8 of 10

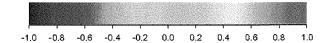
FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 57 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye or 0100

H3DV6-SN:6170

August 23, 2012

# Deviation from Isotropy in Air Error (φ, θ), f = 900 MHz





Uncertainty of Spherical Isotropy Assessment: ± 2.6% (k=2)

Certificate No: H3-6170\_Aug12

Page 9 of 10

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 58 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 30 01 60

H3DV6- SN:6170 August 23, 2012

### DASY/EASY - Parameters of Probe: H3DV6 - SN:6170

#### **Other Probe Parameters**

Sensor Arrangement	Rectangular
Connector Angle (°)	-2.4
Mechanical Surface Detection Mode	enabled
Optical Surface Detection Mode	disabled
Probe Overall Length	337 mm
Probe Body Diameter	10 mm
Tip Length	20 mm
Tip Diameter	6 mm
Probe Tip to Sensor X Calibration Point	3 mm
Probe Tip to Sensor Y Calibration Point	3 mm
Probe Tip to Sensor Z Calibration Point	3 mm

Certificate No: H3-6170\_Aug12

Page 10 of 10

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 59 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 33 01 00

#### Calibration Laboratory of Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





Schweizerischer Kalibrierdienst Service suisse d'étalonnage Servizio svizzero di taratura Swiss Calibration Service

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

C

S

Client PC Test

Certificate No: CD835V3-1003\_Feb11

#### **CALIBRATION CERTIFICATE** CD835V3 - SN: 1003 Object QA CAL-20.v5 Calibration procedure(s) Calibration procedure for dipoles in air February 08, 2011 Calibration date: This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Primary Standards ID# Cal Date (Certificate No.) Scheduled Calibration Power meter EPM-442A GB37480704 06-Oct-10 (No. 217-01266) Oct-11 Power sensor HP 8481A US37292783 06-Oct-10 (No. 217-01266) Oct-11 Probe ER3DV6 SN: 2336 29-Dec-10 (No. ER3-2336\_Dec10) Dec-11 Probe H3DV6 SN: 6065 29-Dec-10 (No. H3-6065\_Dec10) Dec-11 DAE4 SN: 781 20-Oct-10 (No. DAE4-781\_Oct10) Oct-11 Secondary Standards Check Date (in house) Scheduled Check ID# Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-10) In house check: Oct-11 Power sensor HP 8482H SN: 3318A09450 09-Oct-09 (in house check Oct-10) In house check: Oct-11 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-10) In house check: Oct-11 18-Oct-01 (in house check Oct-10) Network Analyzer HP 8753E US37390585 In house check: Oct-11 RF generator E4433B MY 41000675 03-Nov-04 (in house check Oct-09) In house check: Oct-11 Name Function Calibrated by: Claudio Leubler Laboratory Technician Katja Pokovic Approved by: Technical Manager Issued: February 10, 2011 This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

Certificate No: CD835V3-1003\_Feb11

Page 1 of 6

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 60 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 00 01 60

#### Calibration Laboratory of

Schmid & Partner Engineering AG Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
S Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)
The Swiss Accreditation Service is one of the signatories to the EA
Multilateral Agreement for the recognition of calibration certificates

#### References

[1] ANSI-C63.19-2006

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

[2] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other
  axes. In coincidence with the standards [1, 2], the measurement planes (probe sensor center) are
  selected to be at a distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate.
   All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E- field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1, 2], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
  antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field
  scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field
  value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the
  dipole surface at the feed point.

Certificate No: CD835V3-1003\_Feb11 Page 2 of 6

FCC ID: A3LGTI9023	PCTEST'	HAC (RF EMISSIONS) TEST REPORT		Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 61 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 01 01 00

#### 1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 180 mm
Frequency	835 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

#### 2 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.458 A/m
Uncertainty for H-field measurement: 8.2% (k=2)		

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end-	100 mW forward power	170.7 V/m
Maximum measured above low end	100 mW forward power	161.3 V/m
Averaged maximum above arm	100 mW forward power	166.0 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

#### 3 Appendix

#### 3.1 Antenna Parameters

Frequency	Return Loss	Impedance
800 MHz	16.6 dB	(41.9 – j11.1) Ohm
835 MHz	24.1 dB	( 48.2 + j5.9 ) Ohm
900 MHz	16.5 dB	( 58.5 – j14.0 ) Ohm
950 MHz	17.9 dB	( 49.3 + j12.8 ) Ohm
960 MHz	12.9 dB	( 62.2 + j22.8 ) Ohm

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

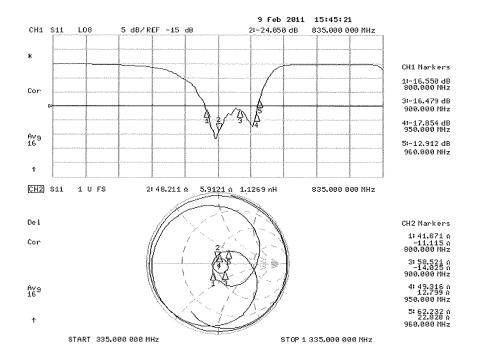
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD835V3-1003\_Feb11 Page 3 of 6

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 62 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F aye 02 01 00

#### 3.3 Measurement Sheets

#### 3.3.1 Return Loss and Smith Chart



Certificate No: CD835V3-1003\_Feb11

Page 4 of 6

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 63 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 03 01 60

#### 3.3.3 DASY4 H-field Result

Date/Time: 08.02.2011 13:00:11

Test Laboratory: SPEAG Lab2

HAC RF\_CD835\_1003\_H\_110208\_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz Medium parameters used:  $\sigma=0$  mho/m,  $\epsilon_r=1$ ;  $\rho=1$  kg/m³ Phantom section: RF Section Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

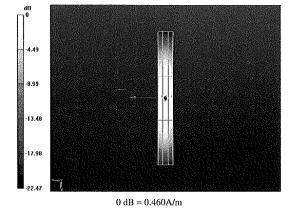
- Probe: H3DV6 SN6065; ; Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole H-Field measurement @ 835MHz/H Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm Maximum value of peak Total field = 0.458 A/m Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm Reference Value = 0.488 A/m; Power Drift = -0.0088 dB Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.376	0.398	<b>0.379</b>
M4	M4	<b>M4</b>
Grid 4	Grid 5	Grid 6
0.435	0.458	0.434
M4	M4	M4
Grid 7	Grid 8	Grid 9
0.388	0.407	<b>0.381</b>
M4	M4	<b>M4</b>



Certificate No: CD835V3-1003\_Feb11

Page 5 of 6

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 64 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 04 01 00

#### 3.3.2 DASY4 E-field Result

Date/Time: 08.02.2011 13:58:56

Test Laboratory: SPEAG Lab2

HAC RF\_CD835\_1003\_E\_110208\_CL

DUT: HAC-Dipole 835 MHz; Type: CD835V3; Serial: 1003

Communication System: CW; Frequency: 835 MHz

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 835MHz/E Scan - measurement distance from the probe sensor center to CD835 Dipole = 10mm/Hearing Aid Compatibility Test (41x361x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 170.7 V/m

Probe Modulation Factor = 1.000

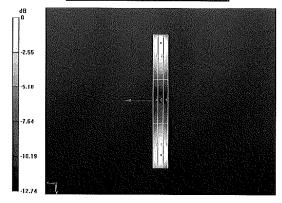
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 123.4 V/m; Power Drift = 0.02 dB

Hearing Aid Near-Field Category: M4 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
164.3	170.7	164.5
M4	M4	M4
Grid 4	Grid 5	Grid 6
85.8	90.5	88.8
M4	M4	M4
Grid 7	Grid 8	Grid 9
<b>152.9</b>	161.3	158.3
<b>M4</b>	M4	M4



0 dB = 170.7 V/m

Certificate No: CD835V3-1003\_Feb11

Page 6 of 6

FCC ID: A3LGTI9023	PCTEST*	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 65 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 03 01 00

#### Calibration Laboratory of

Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
S Swiss Calibration Service

Certificate No: CD1880V3-1137\_Feb11/2

Issued: February 23, 2011

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

Accreditation No.: SCS 108

Client PC Test

CALIBRATION CERTIFICATE (Replacement of No: CD1880V3-1137 Feb11) CD1880V3 - SN: 1137 Object QA CAL-20.v5 Calibration procedure(s) Calibration procedure for dipoles in air Calibration date: February 09, 2011 This calibration certificate documents the traceability to national standards, which realize the physical units of measurements (SI). All calibrations have been conducted in the closed laboratory facility: environment temperature (22 ± 3)°C and humidity < 70%. Calibration Equipment used (M&TE critical for calibration) Cal Date (Certificate No.) Primary Standards Scheduled Calibration GB37480704 Power meter EPM-442A 06-Oct-10 (No. 217-01266) Oct-11 Power sensor HP 8481A HS37292783 06-Oct-10 (No. 217-01266) Oct-11 Probe ER3DV6 SN: 2336 29-Dec-10 (No. ER3-2336\_Dec10) Dec-11 Probe H3DV6 SN: 6065 29-Dec-10 (No. H3-6065\_Dec10) Dec-11 DAE4 SN: 781 20-Oct-10 (No. DAE4-781\_Oct10) Oct-11 Secondary Standards Check Date (in house) ID# Scheduled Check Power meter Agilent 4419B SN: GB42420191 09-Oct-09 (in house check Oct-10) In house check: Oct-11 Power sensor HP 8482H SN: 3318A09450 09-Oct-09 (in house check Oct-10) In house check: Oct-11 Power sensor HP 8482A SN: US37295597 09-Oct-09 (in house check Oct-10) In house check: Oct-11 US37390585 Network Analyzer HP 8753E 18-Oct-01 (in house check Oct-10) In house check: Oct-11 RF generator E4433B MY 41000675 03-Nov-04 (in house check Oct-09) In house check: Oct-11 Name Function Calibrated by: Claudio Leubler Laboratory Technician Katja Pokovic Approved by: Technical Manager

Certificate No: CD1880V3-1137\_Feb11/2

Page 1 of 9

This calibration certificate shall not be reproduced except in full without written approval of the laboratory.

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 66 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		raye oo ol oo

#### Calibration Laboratory of

Schmid & Partner
Engineering AG
Zeughausstrasse 43, 8004 Zurich, Switzerland





S Schweizerischer Kalibrierdienst
C Service suisse d'étalonnage
Servizio svizzero di taratura
S Swiss Calibration Service

Accreditation No.: SCS 108

Accredited by the Swiss Accreditation Service (SAS)

The Swiss Accreditation Service is one of the signatories to the EA

Multilateral Agreement for the recognition of calibration certificates

#### References

[1] ANSI-C63.19-2007

American National Standard for Methods of Measurement of Compatibility between Wireless Communications Devices and Hearing Aids.

#### Methods Applied and Interpretation of Parameters:

- Coordinate System: y-axis is in the direction of the dipole arms. z-axis is from the basis of the antenna
  (mounted on the table) towards its feed point between the two dipole arms. x-axis is normal to the other
  axes. In coincidence with the standards [1], the measurement planes (probe sensor center) are
  selected to be at a distance of 10 mm above the top edge of the dipole arms.
- Measurement Conditions: Further details are available from the hardcopies at the end of the certificate.
   All figures stated in the certificate are valid at the frequency indicated. The forward power to the dipole connector is set with a calibrated power meter connected and monitored with an auxiliary power meter connected to a directional coupler. While the dipole under test is connected, the forward power is adjusted to the same level.
- Antenna Positioning: The dipole is mounted on a HAC Test Arch phantom using the matching dipole positioner with the arms horizontal and the feeding cable coming from the floor. The measurements are performed in a shielded room with absorbers around the setup to reduce the reflections. It is verified before the mounting of the dipole under the Test Arch phantom, that its arms are perfectly in a line. It is installed on the HAC dipole positioner with its arms parallel below the dielectric reference wire and able to move elastically in vertical direction without changing its relative position to the top center of the Test Arch phantom. The vertical distance to the probe is adjusted after dipole mounting with a DASY5 Surface Check job. Before the measurement, the distance between phantom surface and probe tip is verified. The proper measurement distance is selected by choosing the matching section of the HAC Test Arch phantom with the proper device reference point (upper surface of the dipole) and the matching grid reference point (tip of the probe) considering the probe sensor offset. The vertical distance to the probe is essential for the accuracy.
- Feed Point Impedance and Return Loss: These parameters are measured using a HP 8753E Vector Network Analyzer. The impedance is specified at the SMA connector of the dipole. The influence of reflections was eliminating by applying the averaging function while moving the dipole in the air, at least 70cm away from any obstacles.
- E- field distribution: E field is measured in the x-y-plane with an isotropic ER3D-field probe with 100 mW forward power to the antenna feed point. In accordance with [1], the scan area is 20mm wide, its length exceeds the dipole arm length (180 or 90mm). The sensor center is 10 mm (in z) above the top of the dipole arms. Two 3D maxima are available near the end of the dipole arms. Assuming the dipole arms are perfectly in one line, the average of these two maxima (in subgrid 2 and subgrid 8) is determined to compensate for any non-parallelity to the measurement plane as well as the sensor displacement. The E-field value stated as calibration value represents the maximum of the interpolated 3D-E-field, 10mm above the dipole surface.
- H-field distribution: H-field is measured with an isotropic H-field probe with 100mW forward power to the
  antenna feed point, in the x-y-plane. The scan area and sensor distance is equivalent to the E-field
  scan. The maximum of the field is available at the center (subgrid 5) above the feed point. The H-field
  value stated as calibration value represents the maximum of the interpolated H-field, 10mm above the
  dipole surface at the feed point.

Certificate No: CD1880V3-1137\_Feb11/2 Page 2 of 9

FCC ID: A3LGTI9023	PCTEST	HAC (RF EMISSIONS) TEST REPORT	SAMSUNG	Reviewed by: Quality Manager	
Filename:	Test Dates:	EUT Type:			
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Page 67 of 80	

#### 1. Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1880 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

#### 2. Maximum Field values

H-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured	100 mW forward power	0.460 A/m
Uncertainty for H-field measurement: 8.2% (k=2)		

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	139.0 V/m
Maximum measured above low end	100 mW forward power	134.5 V/m
Averaged maximum above arm	100 mW forward power	136.8 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

#### 3. Appendix

#### 3.1 Antenna Parameters

Frequency	Return Loss	Impedance
1730 MHz	23.0 dB	( 49.6 + j7.1 ) Ohm
1880 MHz	21.2 dB	( 51.1 + j8.7 ) Ohm
1900 MHz	21.8 dB	( 53.3 + j7.7 ) Ohm
1950 MHz	28.1 dB	( 54.1 – j0.2 ) Ohm
2000 MHz	20.5 dB	( 41.4 – j0.8 ) Ohm

#### 3.2 Antenna Design and Handling

The calibration dipole has a symmetric geometry with a built-in two stub matching network, which leads to the enhanced bandwidth.

The dipole is built of standard semirigid coaxial cable. The internal matching line is open ended. The antenna is therefore open for DC signals.

Do not apply force to dipole arms, as they are liable to bend. The soldered connections near the feedpoint may be damaged. After excessive mechanical stress or overheating, check the impedance characteristics to ensure that the internal matching network is not affected.

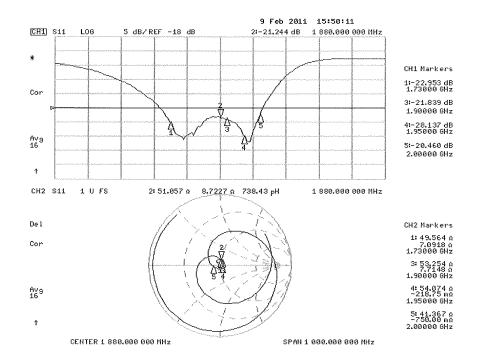
After long term use with 40W radiated power, only a slight warming of the dipole near the feedpoint can be measured.

Certificate No: CD1880V3-1137\_Feb11/2 Page 3 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 68 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		rage 00 01 00

#### 3.3 Measurement Sheets

#### 3.3.1 Return Loss and Smith Chart



Certificate No: CD1880V3-1137\_Feb11/2

Page 4 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 69 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		F age 03 01 60

Date/Time: 09.02.2011 11:34:28

Test Laboratory: SPEAG Lab2

HAC\_RF\_CD1880\_1137\_H\_110208\_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz Medium parameters used:  $\sigma$  = 0 mho/m,  $\epsilon_r$  = 1;  $\rho$  = 1 kg/m³ Phantom section: RF Section

DASY5 Configuration:

• Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

Sensor-Surface: (Fix Surface)

• Electronics: DAE4 Sn781; Calibrated: 20.10.2010

• Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070

Measurement SW: DASY52, V52.6.1 Build (408)

Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

### Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 0.460 A/m

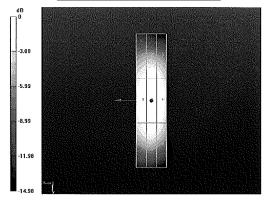
Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.487 A/m; Power Drift = 0.0057 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
<b>0.401</b>	<b>0.418</b>	<b>0.396</b>
<b>M2</b>	<b>M2</b>	<b>M2</b>
Grid 4	Grid 5	Grid 6
0.443	<b>0.460</b>	0.435
M2	<b>M2</b>	M2
Grid 7	Grid 8	Grid 9
<b>0.409</b>	0.426	0.399
<b>M2</b>	M2	M2



0 dB = 0.460 A/m

Certificate No: CD1880V3-1137\_Feb11/2

Page 5 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 70 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Page 70 01 60

#### 3.3.3 DASY4 E-Field Result

Date/Time: 08.02.2011 16:54:42

Test Laboratory: SPEAG Lab2

HAC\_RF\_CD1880\_1137\_E\_110208\_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1880 MHz

Medium parameters used:  $\sigma = 0$  mho/m,  $\varepsilon_r = 1$ ;  $\rho = 1000$  kg/m<sup>3</sup>

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

### Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm/Hearing Aid Compatibility Test (41x181x1);

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 139.0 V/m

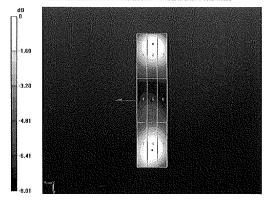
Probe Modulation Factor = 1.000

Device Reference Point: 0, 0, -6.3 mm

Reference Value = 138.8 V/m; Power Drift = -0.05 dB Hearing Aid Near-Field Category; M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
131.8	139.0	135.0
M2	M2	M2
Grid 4	Grid 5	Grid 6
84.076	87.648	85.767
M3	M3	M3
Grid 7	Grid 8	Grid 9
131.1	134.5	130.5
M2	M2	M2



0 dB = 139.0 V/m

Certificate No: CD1880V3-1137\_Feb11/2

Page 6 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 71 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage / 1 01 00

#### 4. Additional Measurements

#### 4.1 Measurement Conditions

DASY system configuration, as far as not given on page 1.

DASY Version	DASY5	V52.6.1 (408)
DASY PP Version	SEMCAD X	V14.4.2 (2595)
Phantom	HAC Test Arch	SD HAC P01 BA, #1070
Distance Dipole Top - Probe Center	10 mm	
Scan resolution	dx, dy = 5 mm	area = 20 x 90 mm
Frequency	1730 MHz ± 1 MHz	
Forward power at dipole connector	20.0 dBm = 100mW	
Input power drift	< 0.05 dB	

#### 4.1.1 Maximum Field values

H-field 10 mm above dipole surface	condition	interpolated maximum
Maximum measured	100 mW forward power	0.489 A/m
Uncertainty for H-field measurement: 8.2% (k=2)		

E-field 10 mm above dipole surface	condition	Interpolated maximum
Maximum measured above high end	100 mW forward power	152.7 V/m
Maximum measured above low end	100 mW forward power	150.2 V/m
Averaged maximum above arm	100 mW forward power	151.5 V/m

Uncertainty for E-field measurement: 12.8% (k=2)

Certificate No: CD1880V3-1137\_Feb11/2

Page 7 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 72 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye 12 01 00

#### 4.1.2 DASY4 H-field result

Date/Time: 09.02.2011 11:27:03

Test Laboratory: SPEAG Lab2

HAC\_RF\_CD1880\_1137\_H\_1730\_110208\_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz Medium parameters used:  $\sigma=0$  mho/m,  $\epsilon_r=1$  ;  $\rho=1$  kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

• Probe: H3DV6 - SN6065; ; Calibrated: 29.12.2010

• Sensor-Surface: (Fix Surface)

• Electronics: DAE4 Sn781; Calibrated: 20.10.2010

• Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070

Measurement SW: DASY52, V52.6.1 Build (408)

Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

### Dipole H-Field measurement @ 1880MHz/H Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

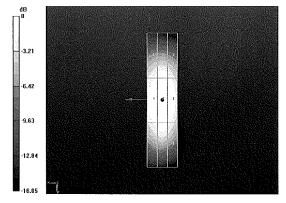
Maximum value of peak Total field = 0.489 A/m Probe Modulation Factor = 1.000

Probe Modulation Factor = 1.000 Device Reference Point: 0, 0, -6.3 mm

Reference Value = 0.519 A/m; Power Drift = 0.02 dB Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak H-field in A/m

Grid 1	Grid 2	Grid 3
0.407	0.424	0.403
M2	M2	M2
Grid 4	Grid 5	Grid 6
<b>0.467</b>	<b>0.489</b>	0.462
M2	<b>M2</b>	M2
Grid 7	Grid 8	Grid 9
<b>0.418</b>	0.437	<b>0.409</b>
<b>M2</b>	M2	<b>M2</b>



0 dB = 0.490 A/m

Certificate No: CD1880V3-1137\_Feb11/2

Page 8 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 73 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		rage 73 01 00

#### 4.1.3 DASY4 E-field result

Date/Time: 08.02.2011 16:26:13

Test Laboratory: SPEAG Lab2

HAC\_RF\_CD1880\_1137\_E\_1730\_110208\_CL

DUT: HAC Dipole 1880 MHz; Type: CD1880V3; Serial: 1137

Communication System: CW; Frequency: 1730 MHz

Medium parameters used:  $\sigma = 0$  mho/m,  $\epsilon_r = 1$ ;  $\rho = 1000$  kg/m³

Phantom section: RF Section

Measurement Standard: DASY5 (IEEE/IEC/ANSI C63.19-2007)

#### DASY5 Configuration:

- Probe: ER3DV6 SN2336; ConvF(1, 1, 1); Calibrated: 29.12.2010
- Sensor-Surface: (Fix Surface)
- Electronics: DAE4 Sn781; Calibrated: 20.10.2010
- Phantom: HAC Test Arch with AMCC; Type: SD HAC P01 BA; Serial: 1070
- Measurement SW: DASY52, V52.6.1 Build (408)
- Postprocessing SW: SEMCAD X, V14.4.2 Build (2595)

Dipole E-Field measurement @ 1880MHz/E Scan - measurement distance from the probe sensor center to CD1880 Dipole = 10mm @ 1730 MHz/Hearing Aid Compatibility Test (41x181x1):

Measurement grid: dx=5mm, dy=5mm

Maximum value of peak Total field = 152.7 V/m

Probe Modulation Factor = 1.000

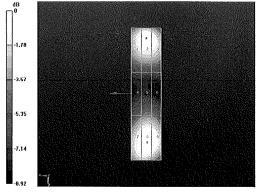
Device Reference Point: 0, 0, -6.3 mm

Reference Value = 156.8 V/m; Power Drift = 0.0092 dB

Hearing Aid Near-Field Category: M2 (AWF 0 dB)

Peak E-field in V/m

Grid 1	Grid 2	Grid 3
143.8	150.2	144.8
M2	M2	M2
Grid 4	Grid 5	Grid 6
<b>97.621</b>	103.8	102.2
M3	M3	M3
Grid 7	Grid 8	Grid 9
145.9	152.7	149.2
M2	M2	M2



0 dB = 152.7 V/m

Certificate No: CD1880V3-1137\_Feb11/2

Page 9 of 9

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager	
Filename:	Test Dates:		EUT Type:		Page 74 of 80
0Y1210311563.A3L	October 18-24, 2012		Portable Handset		rage 74 01 60

#### 15. CONCLUSION

The measurements indicate that the wireless communications device complies with the HAC limits specified in accordance with the ANSI C63.19 Standard and FCC WT Docket No. 01-309 RM-8658. Precise laboratory measures were taken to assure repeatability of the tests. The tested device complies with the requirements in respect to all parameters specific to the test. The test results and statements relate only to the item(s) tested.

Please note that the M-rating for this equipment only represents the field interference possible against a hypothetical and typical hearing aid. The measurement system and techniques presented in this evaluation are proposed in the ANSI standard as a means of best approximating wireless device compatibility with a hearing-aid. The literature is under continual re-construction.

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 75 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 75 01 60

#### 16. REFERENCES

- ANSI/IEEE C63.19-2007, American National Standard for Methods of Measurement of Compatibility between Wireless Communication Devices and Hearing Aids.", New York, NY, IEEE, June 2007
- FCC Public Notice DA 06-1215, Wireless Telecommunications Bureau and Office of Engineering and Technology Clarify Use of Revised Wireless Phone Hearing Aid Compatibility Standard, June 6, 2006
- 3. Berger, H. S., "Compatibility Between Hearing Aids and Wireless Devices," Electronic Industries Forum, Boston, MA, May, 1997
- 4. Berger, H. S., "Hearing Aid and Cellular Phone Compatibility: Working Toward Solutions," Wireless Telephones and Hearing Aids: New Challenges for Audiology, Gallaudet University, Washington, D.C., May, 1997 (To be reprinted in the American Journal of Audiology).
- 5. Berger, H. S., "Hearing Aid Compatibility with Wireless Communications Devices, " IEEE International Symposium on Electromagnetic Compatibility, Austin, TX, August, 1997.
- 6. Bronaugh, E. L., "Simplifying EMI Immunity (Susceptibility) Tests in TEM Cells," in the 1990 IEEE International Symposium on Electromagnetic Compatibility Symposium Record, Washington, D.C., August 1990, pp. 488-491
- 7. Byme, D. and Dillon, H., The National Acoustics Laboratory (NAL) New Procedure for Selecting the Gain and Frequency Response of a Hearing Aid, Ear and Hearing 7:257-265, 1986.
- 8. Crawford, M. L., "Measurement of Electromagnetic Radiation from Electronic Equipment using TEM Transmission Cells, "U.S. Department of Commerce, National Bureau of Standards, NBSIR 73-306, Feb. 1973.
- Crawford, M. L., and Workman, J. L., "Using a TEM Cell for EMC Measurements of Electronic Equipment," U.S. Department of Commerce, National Bureau of Standards. Technical Note 1013, July 1981.
- EHIMA GSM Project, Development phase, Project Report (1<sup>st</sup> part) Revision A. Technical-Audiological Laboratory and Telecom Denmark, October 1993.
- 11. EHIMA GSM Project, Development phase, Part II Project Report. Technical-Audiological Laboratory and Telecom Denmark, June 1994.
- 12. EHIMA GSM Project Final Report, Hearing Aids and GSM Mobile Telephones: Interference Problems, Methods of Measurement and Levels of Immunity. Technical-Audiological Laboratory and Telecom Denmark, 1995.
- 13. HAMPIS Report, Comparison of Mobile phone electromagnetic near field with an upscaled electromagnetic far field, using hearing aid as reference, 21 October 1999.
- 14. Hearing Aids/GSM, Report from OTWIDAM, Technical-Audiological Laboratory and Telecom Denmark, April 1993.

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 76 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Fage 10 01 00

- 15. IEEE 100, The Authoritative Dictionary of IEEE Standards Terms, Seventh Edition.
- 16. Joyner, K. H, et. al., Interference to Hearing Aids by the New Digital Mobile Telephone System, Global System for Mobile (GSM) Communication Standard, National Acoustic Laboratory, Australian Hearing Series, Sydney 1993.
- 17. Joyner, K. H., et. al., Interference to Hearing Aids by the Digital Mobile Telephone System, Global System for Mobile Communications (GSM), NAL Report #131, National Acoustic Laboratory, Australian Hearing Series, Sydney, 1995.
- 18. Kecker, W. T., Crawford, M. L., and Wilson, W. A., "Contruction of a Transverse Electromagnetic Cell", U.S. Department of Commerce, National Bureau of Standards, Technical Note 1011, Nov. 1978.
- 19. Konigstein, D., and Hansen, D., "A New Family of TEM Cells with enlarged bandwidth and Optimized working Volume," in the Proceedings of the 7<sup>th</sup> International Symposium on EMC, Zurich, Switzerland, March 1987; 50:9, pp. 127-132.
- 20. Kuk, F., and Hjorstgaard, N. K., "Factors affecting interference from digital cellular telephones," Hearing Journal, 1997; 50:9, pp 32-34.
- 21. Ma, M. A., and Kanda, M., "Electromagnetic Compatibility and Interference Metrology," U.S. Department of Commerce, National Bureau of Standards, Technical Note 1099, July 1986, pp. 17-43.
- 22. Ma, M. A., Sreenivashiah, I., and Chang, D. C., "A Method of Determining the Emission and Susceptibility Levels of Electrically Small Objects Using a TEM Cell," U.S. Department of Commerce, National Bureau of Standards, Technial Note 1040, July 1981.
- 23. McCandless, G. A., and Lyregaard, P. E., Prescription of Gain/Output (POGO) for Hearing Aids, Hearing Instruments 1:16-21, 1983
- 24. Skopec, M., "Hearing Aid Electromagnetic Interference from Digital Wireless Telephones, "IEEE Transactions on Rehabilitation Engineering, vol. 6, no. 2, pp. 235-239, June 1998.
- 25. Technical Report, GSM 05.90, GSM EMC Considerations, European Telecommunications Standards Institute, January 1993.
- 26. Victorian, T. A., "Digital Cellular Telephone Interference and Hearing Aid Compatibility—an Update," Hearing Journal 1998; 51:10, pp. 53-60
- 27. Wong, G. S. K., and Embleton, T. F. W., eds., AIP Handbook of Condenser Microphones: Theory, Calibration and Measurements, AIP Press.

FCC ID: A3LGTI9023	HAC (RF EMISSIONS) TEST REPORT		SAMSUNG	Reviewed by: Quality Manager
Filename:	Test Dates:	EUT Type:		Page 77 of 80
0Y1210311563.A3L	October 18-24, 2012	Portable Handset		Faye // 0100